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(54) METHOD OF PRODUCING ORGANIC EL ELEMENTS, ORGANIC EL ELEMENTS AND ORGANIC EL DISPLAY DEVICE

VERFAHREN ZUR HERSTELLUNG ORGANISCHER ELEKTROLUMINESZENZELEMENTE, ORGANISCHE ELEKTROLUMINESZENZELEMENTE UND ORGANISCHE ELEKTROLUMINESZENZANZEIGE-VORRICHTUNG

PROCEDE DE PRODUCTION D'ELEMENTS EL ORGANIQUES, ELEMENTS EL ORGANIQUES ET DISPOSITIF D'AFFICHAGE EL ORGANIQUE

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- **KANBE, Sadao, Selko Epson Corporation
Suwa-shi, Nagano-ken 392 (JP)**

(30) Priority: 25.11.1996 JP 31382896

**(74) Representative: Kenyon, Sarah Elizabeth et al
Miller Sturt Kenyon
9 John Street
London WC1N 2ES (GB)**

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(73) Proprietor: **SEIKO EPSON CORPORATION**
Shinjuku-ku, Tokyo 163-0811 (JP)

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(72) Inventors:

- MIYASHITA, Satoru, Seiko Epson Corporation
Suwa-shi, Nagano-ken 392 (JP)
- KIGUCHI, Hiroshi, Seiko Epson Corporation
Suwa-shi, Nagano-ken 392 (JP)
- SHIMODA, Tatsuya, Seiko Epson Corporation
Suwa-shi, Nagano-ken 392 (JP)

Description**FIELD OF THE INVENTION**

5 [0001] The present invention relates to a method of manufacturing an organic electroluminescent (EL) element, an organic EL element, and an organic'EL display device.

BACKGROUND ART

10 [0002] An organic EL element is an element which has a configuration in which a thin film containing a fluorescent organic compound is held between a cathode and an anode. In the organic EL element, electrons and holes are injected from the respective electrodes into the thin film to generate excitons through the recombination of the electrons and holes . The organic EL element produces luminescence by utilizing emission of light (fluorescence or phosphorescence) at the deactivation of the excitons.

15 [0003] The features of the organic EL element is that it is possible to obtain a high intensity surface luminescence on the order of 100 to 100,000 cd/m² at a low voltage of less than 10V, and that it is possible to produce luminescence of from blue to red by the selection of the kind of fluorescent material.

20 [0004] The organic EL element is drawing attraction as a device for realizing a large area full color display element at a low cost (see, Technical Reports of the Society of Electronic Information and Communications, Vol. 89, No. 106, 1989, p. 49). According to the report, bright luminescence of blue, green and red were obtained by forming a luminescent layer using an organic luminescent material which emits strong fluorescence. This fact is considered to mean that it is possible to realize a high brightness full color display by using an organic coloring matter which emits strong fluorescence in a thin film state and has less pin hole defects.

25 [0005] In addition, in Japanese Laid-Open Publication No. Hei 5-78655, there is proposed to use an organic luminescent layer containing a luminescent material which is formed of a mixture of an organic charging material and an organic luminescent material, thereby obtaining a high brightness full color element by preventing quenching due to higher concentration as well as expanding the latitude in the selection of the luminescent material.

30 [0006] Further, in Appl. Phys. Lett. Vol. 64, 1994, p. 815, it is reported that a white luminescence was obtained by using polyvinyl carbazole (PVK) as a luminescent material and doping it with coloring matters corresponding to three primary colors R, G and B. However, in neither of the above references, the configuration or the method of manufacture of an actual full color display panel is not shown.

35 [0007] In the organic thin film EL elements using the organic luminescent materials described above, in order to realize a full color display device, it is necessary to arrange organic luminescent layers which emit any one of the three primary colors for the respective pixels . However, there is a problem in that a polymer or precursor that forms the organic luminescent layer lacks a sufficient resistance to a patterning process such as photolithography, so that it is very difficult to carry out patterning with highly precision.

40 [0008] Further, when several organic layers are to be formed by a vacuum deposition method, it takes a long time. Therefore, such a method cannot be said to be an efficient method of manufacturing the element.

SUMMARY OF THE INVENTION

45 [0009] It is an object of the present invention to provide a method of manufacturing an organic EL element which makes it possible to carry out patterning easily and precisely, can attain optimization of a film design in a simple manner, and has excellent luminescence characteristics, as well as to provide an organic EL element and an organic EL display device.

[0010] Thus, according to one aspect of the present invention, there is provided a method of manufacturing an organic EL element, comprising:

50 forming first electrodes on or above a transparent substrate;
 forming a luminescent layer on each of the first electrodes or a layer formed on or above each of the first electrodes by discharging a liquid composition including an organic emitting material by means of an ink jet method;
 forming a second electrode on or above the luminescent layers; and
 disposing a protective material on or above the second electrode.

55 [0011] According to another aspect of the present invention, there is provided an organic EL device, comprising:

a transparent substrate;
 first electrodes provided on or above the transparent substrate;

a luminescent layer formed of an organic emitting material on or above each of the first electrodes, an edge of the luminescent layer being positioned within an area occupied by the respective first electrode; a second electrode on or above the luminescent layers; and a protective film formed on or above the second electrode.

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[0012] In the present invention, it is preferable that the organic compound is a polymer organic compound. In this case, it is preferable that the polymer organic compound is a hole injection and transfer type material. Preferably, such a polymer organic compound is a polyphenylene vinylene or its derivative or a copolymer which contains at least either one of these compounds.

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[0013] In this connection, when an organic luminescent material itself is not a hole injection and transfer type material, as is the case in the above-mentioned polymer organic compound, it is possible to add a hole injection and transfer type material to the luminescent layer in addition to the luminescent material.

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[0014] Further, it is also preferred that three luminescent layers having different colours are formed, in which the at least two colours out of the luminescent layers of three colours are patterned by means of an ink-jet method. The three colours are red, green and blue, and it is preferable that the red luminescent layer and the green luminescent layer are patterned by means of an ink-jet method. In this case, it is more preferable that the blue luminescent layer is formed by a vacuum deposition method. Further, it is preferable that the blue luminescent layer is made of an electron injection and transfer type material, such as an aluminium quinololinol complex.

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[0015] In the manufacturing method for the organic EL element according to the present invention, it is preferable that at least one luminescent layer is laminated with a hole injection and transfer layer, and it is also preferable that a protective film is formed on the counter electrode.

[0016] In the manufacturing method for the organic EL element of the present invention, it is preferable that the transparent substrate is provided with thin film transistors for driving respective pixels.

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[0017] Further, it is preferable that the pixel electrodes are formed into a transparent pixel electrode.

[0018] Furthermore, the organic EL element of the present invention is provided with a transparent substrate, pixel electrodes formed on the transparent substrate, at least one luminescent layers having a certain color and made of an organic compound, the luminescent layer being patterned on the pixel electrodes by an ink-jet method, and a counter electrode formed on the luminescent layer.

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[0019] It is preferable that the organic compound is a polymer organic compound, and it is more preferable that the polymer organic compound is a hole injection and transfer type material.

[0020] Moreover, it is preferable that the polymer organic compound is a polyphenylene vinylene or its derivative or a copolymer containing at least one of them.

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[0021] It is preferred that the at least luminescent layer includes three layers having different three colors, and it is preferable that two layers thereof in the luminescent layers of three colors are patterned by an ink-jet method. The three colors are red, green and blue, and it is more preferable that the red luminescent layer and the green luminescent layer are separately patterned by an ink-jet method. In this case, it is more preferable that the blue luminescent layer is formed by a vacuum deposition method.

[0022] It is preferable that the blue luminescent layer is made of an electron injection and transfer material. As for such a blue luminescent layer, a layer containing an aluminum quinololinol complex can be mentioned.

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[0023] Moreover, it is preferable that at least one luminescent layer is laminated with a hole injection and transfer type layer, and it is more preferable that a protective film is formed on the cathode.

[0024] Furthermore, it is preferable that the pixel electrodes are formed into a transparent pixel electrode.

[0025] Moreover, the organic EL display device according to the present invention is characterized in that it includes the organic EL element described in the above.

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BRIEF DESCRIPTION OF THE DRAWINGS

[0026]

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Fig. 1 is a sectional view which shows a first embodiment of a manufacturing method for an organic EL element according to the present invention.

Fig. 2 is a sectional view which shows a second embodiment of a manufacturing method for an organic EL element according to the present invention.

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Fig. 3 is a sectional view which shows a third embodiment of a manufacturing method for an organic EL element according to the present invention.

Fig. 4 is a sectional view which shows a fourth embodiment of a manufacturing method for an organic EL element according to the present invention.

Fig. 5 is a sectional view which shows a fifth embodiment of a manufacturing method for an organic EL element

according to the preset invention.

Fig. 6 is a sectional view which shows an example of the organic EL element according to the present invention.

Fig. 7 is a sectional view which shows an example of an organic EL display device using the organic EL element according to the present invention.

5 Fig. 8 is a diagram which shows an example of an active matrix type organic EL display device using the organic EL element according to the present invention.

Fig. 9 is a sectional view which shows an example of a manufacturing method of the active matrix type organic EL display device.

10 Fig. 10 is a perspective view which shows an example of a configuration of a head for an ink-jet method which is used in the manufacturing method of the organic EL element according to the present invention.

Fig. 11 is a sectional view of the nozzle part of the head for an ink-jet method which is used in the manufacturing method of the organic EL element according to the present invention.

15 Fig. 12 is a diagram which shows another embodiment of an organic EL display device according to the present invention.

Fig. 13 is a schematic perspective view of an organic EL display device according to the present invention.

Fig. 14 is a diagram which shows an example of the waveform of the driving voltage applied to the electrodes.

Fig. 15 is a partial sectional view which shows another embodiment of an organic EL element according to the present invention.

20 PREFERRED EMBODIMENTS OF THE INVENTION

[0027] In the following, the manufacturing method of the organic EL element and the organic EL element according to the present invention will be described in detail based on the preferred embodiments shown in the accompanying drawings.

25 [0028] Fig. 1 shows a first embodiment of the manufacturing method of the organic EL element according to the present invention. This figure shows the manufacturing method of a full color organic EL element with three colors. As shown in the figure, this invention is directed to a method of manufacturing an organic EL element which comprises a step of forming pixel electrodes 101, 102 and 103 on a transparent substrate (transparent support) 104, a step of patterning luminescent layers 106 and 107 which are made of organic compounds on the respective pixel electrodes, and a step of forming a cathode 113, wherein the method is characterized in that the formation of the luminescent layers is carried out by means of an ink-jet method.

30 [0029] The transparent substrate 104 functions not only as a support but also as a surface through which light is taken out. Accordingly, the material for the transparent substrate 104 is selected by taking the light-permeability, thermal stability and the like into consideration. As for examples of the material to be used for the transparent substrate, glass, transparent plastic or the like can be mentioned, and among these materials, a substrate made of glass is particularly preferable in view of its excellent heat resistance.

35 [0030] In more details, the first, pixel electrodes 101, 102 and 103 are formed on the transparent substrate 104. As for examples of methods of forming these pixel electrodes, photolithography, vacuum deposition method, sputtering method and pyrosol method can be mentioned. Among these methods, the photolithography is particularly preferable. As for these pixel electrodes, it is preferred that they are formed into transparent pixel electrodes. As for the materials constituting the transparent pixel electrodes, a tin oxide film, an ITO (indium tin oxide) film and a composite oxide film of indium oxide and zinc oxide can be mentioned.

40 [0031] Next, partitioning walls (banks) 105 are formed to fill the spaces between the pixel electrodes.

45 [0032] In this way, it is possible to improve the contrast, to prevent mixing of colors of the luminescent materials, and to prevent light from leaking between the pixels.

50 [0033] As for the materials constituting the banks 105, no particular limitation is imposed, if they have a resistance to the solvent for the EL material. For example, organic material such as acrylic resin, epoxy resin, photosensitive polyimide and the like; and inorganic material such as liquid glass and the like can be mentioned. In this regard, it is to be noted that the banks 105 may be formed into a black resist which is formed by mixing carbon black and the like into the above-mentioned material.

55 [0034] As for examples of the forming method for the banks 105, photolithography and the like can be mentioned.

[0035] Further, organic luminescent layers are formed respectively on the pixel electrodes according to a predetermined pattern. In this case, it is preferable to provide organic luminescent layers with three color types. In this connection, it is preferred that at least one layer among these organic luminescent layers is formed by an ink-jet method.

55 [0036] In the embodiment shown in Fig. 1, a red luminescent layer 106 and a green luminescent layer 107 are formed on the pixel electrodes 101 and 102, respectively, by the ink-jet method.

[0037] In the above descriptions, the term "ink-jet method" is used to mean a method of forming a pixel of one of the three primary colors including red, green and blue or a pixel of at least one color which is intermediate between the

primary colors by dissolving or dispersing a luminescent material in a solvent to obtain a discharge liquid and then discharging the discharge liquid from a head 110 of an ink-jet device 109.

[0038] According to such an ink-jet method, it is possible to carry out fine patterning in a simple manner and in a short time. Further, it is also possible to control easily and freely the luminescent characteristics such as color balance and brightness (luminance) by adjusting the thickness of the layer through adjustment of the discharge amount of the ink or by adjusting the ink concentration.

[0039] When the organic luminescent materials are conjugated polymer precursors described later, the luminescent layers are formed by discharging the luminescent materials by the ink-jet method to carry out patterning, and then conjugating (to form a film) the precursor components by heating or irradiation with light or the like.

[0040] Next, as shown in Fig. 1, a blue luminescent layer 108 is formed on the red luminescent layer 106, the green luminescent layer 107 and the pixel electrode 103. In this way, it is possible not only to form layers having the three primary colors including red, green and blue, but also to bury the level differences between the banks 105 and each of the red luminescent layer 106 and the green luminescent layer 107 so as to be flattened.

[0041] No particular limitation is imposed upon the forming method for the blue luminescent layer 108, and it is possible to form the layer using the general film forming method known as deposition method or wet method, for instance, or using the ink-jet method.

[0042] Further, the blue luminescent layer 108 can be formed of an electron injection and transfer material such as aluminum quinolynol complex. In this case, it is possible to promote the injection and transfer of the carriers so as to improve the luminous efficiency. Furthermore, when such a blue luminescent layer 108 is laminated with red and green luminescent layers formed of a hole injection and transfer material described later, it is also possible to inject and transfer the electrons and the holes from the respective electrodes into these laminated luminescent layers with appropriate balance, thereby enabling to improve the luminous efficiency.

[0043] Moreover, when such a blue luminescent layer 108 is laminated with the red and green luminescent layers made of a hole injection and transfer type material, the function of hole injection and transfer and the function of electron injection and transfer can be assigned separately to different layers, so that optimum design can be selected for the respective materials. No particular limitation is imposed upon the forming method of such an electron injection and transfer layer, and it is possible to form the layer by using, for example, the general film forming method known as deposition method or wet method or the ink-jet method.

[0044] In this connection, as for an organic compound which can form an electron injection and transfer layer, oxadiazole derivative such as PBD, OXD-8 and the like, DSA, aluminum quinolinol complex, Bebq, triazole derivative, azomethine complex, porphine complex, benzoxadiazol and the like can be mentioned. In this case, an electron injection and transfer layer can be formed from just one of these materials, or formed by mixing or laminating one or two or more of them. In addition, the electron injection and transfer layer may be formed by doping a fluorescence dye described later to the organic compound described. Further, the electron injection and transfer layer itself may have a function of luminescence.

[0045] As described above, in this embodiment, organic luminescent layers for two colors are formed by the ink-jet method while the layer for the remaining one color is formed by a different method. Therefore, according to this embodiment, even when a luminescent material which is not so suited for the ink-jet method is used, a full color organic EL element can be formed by using such a material in a combination with other organic luminescent materials that are suited for the ink-jet method, so that the latitude in the design for the EL element will be expanded.

[0046] As for examples of the forming method for the luminescent layer other than the ink-jet method, photolithography method, vacuum deposition method, printing method, transfer method, dipping method, spin coating method, casting method, capillary method, roll coating method, bar coating method and the like can be mentioned.

[0047] Finally, a cathode (a counter electrode) 113 is formed, thereby the organic EL element of the present invention is completed. In this case, it is preferred that the cathode 113 is formed into a metallic thin film electrode, and as for examples of the metal for forming the cathode, Mg, Ag, Al, Li and the like can be mentioned. In addition, a material having small work function can be used for the material for the cathode 113, and for example, alkali metal, alkali earth metal such as Ca and the like, and alloys containing these metals can be used. Such a cathode 113 may be formed using a deposition method, a sputtering method or the like.

[0048] The organic EL element of the present invention is manufactured through the processes described in the above. Namely, as shown in Fig. 1, the pixel electrodes 101 and 102 are provided on the transparent substrate 104, the red luminescent layer 106 and the green luminescent layer 107 which are made of organic compounds are then formed on the pixel electrodes 101 and 102, respectively, by patterning by using the ink-jet method, and then the blue luminescent layer 108 is formed on the luminescent layers 106 and 107 and the pixel electrode 103 by the vacuum deposition method. Thereafter, the cathode 113 is formed on top of the blue luminescent layer 108, thereby the organic EL element according to the present invention is completed.

[0049] Further, as shown in Fig. 6, a protective film 415 may be formed on top of a cathode 413. By forming such a protective film 415, it becomes possible to prevent deterioration, damage, peeling and the like from occurring in the

cathode 413 and in the luminescent layers 406, 407 and 408.

[0050] As for materials for constructing the protective film 415, epoxy resin, acrylic resin, liquid glass and the like can be mentioned. Further, as for examples of the forming method for the protective film 415, spin coating method, casting method, dipping method, bar coating method, roll coating method, capillary method and the like can be mentioned.

[0051] In this embodiment, it is preferable that these luminescent layers are formed of an organic compound, and it is more preferable that these luminescent layers are formed of a polymer organic compound. By providing such luminescent layers that are formed of the organic compound, it is possible to obtain high brightness surface luminescence at low voltages. Further, since luminescent materials can be selected from wide range of field, a rational design for the luminescent element becomes possible.

[0052] In particular, polymer organic compounds have an excellent film formation property, and the luminescent layers composed of polymer organic compounds have an extremely good durability. Further, these polymer organic compounds have a band gap in the visible region and a relatively high electrical conductivity. Among such polymer organic compounds, a conjugated polymer can exhibit such properties prominently.

[0053] As for materials for the organic luminescent layers, polymer organic compound itself, precursor of conjugated organic polymer compound which is to be conjugated (to form a film) by heating or the like, and other materials are used.

[0054] When a precursor prior to conjugation (to form a film) is used as a luminescent material, the viscosity or the like of a discharge liquid used for the ink-jet system can be adjusted easily, so that the patterning is carried out precisely and the luminescence characteristics and the film properties of the luminescent layer can be controlled easily.

[0055] It is preferred that the polymer organic compound forming the luminescent layers is a hole injection and transfer material. In this way, it is possible to promote the injection and transfer of the carriers and thereby to improve the luminous efficiency.

[0056] As for examples of an organic compound which can form the luminescent layers, polyalkylthiophene such as PPV (poly(paraphenylene vinylene)) or its derivative, PTV (poly(2,5-thienylene vinylene)) and the like; polyallylene vinylene such as PFV (poly(2,5-furylene vinylene)) polyparaphenylene, polyalkylfluorene and the like; pyrazoline dimer; quinolizine carboxylic acid; benzopyrylium perchlorate; benzopyranoquinolizine; rubrene; phenanthroline europlum complex and the like can be mentioned. In this case, just one of them or a mixture of two or more of them can be selectively used.

[0057] Among these organic compounds, PPV which is a conjugated organic polymer compound or its derivative is preferable. The precursor prior to conjugation (to form a film) of PPV or its derivative is soluble to water or organic solvent, so that they are suitable for pattern formation by the ink-jet method. Further, it is possible to obtain a thin layer which has high optical quality and excellent durability, since it is a polymer. Furthermore, PPV or its derivative possesses a strong fluorescence, and since it is a conductive polymer in which π -electron of double bond is delocalized on the polymer chain, a thin film of PPV also functions as a hole injection and transfer layer, which makes it possible to obtain an organic EL element having high performance.

[0058] Furthermore, the composition for an organic EL element in a case where a polymer organic compound is used for the material for the luminescent layers may include at least one kind of fluorescent dye in it. By including such fluorescent dye way, it becomes possible to change the luminous property of the luminescent layer. Therefore, the addition of the fluorescent dye is effective as a means, for example, for improving the luminous efficiency of the luminescent layer or for changing the maximum wavelength of light absorption (emitted color) of the luminescent layers.

[0059] Namely, a fluorescent dye can be utilized not only as a material for the luminescent layers but also as a material for the coloring matter which has the luminescence function itself. For example, almost all of the energy of the excitons which are generated by the recombination of carriers on the molecules of a conjugated organic polymer compound such as PPV can be transferred onto the molecules of the fluorescent dye. In this case, the current quantum efficiency of the EL element is also increased, because the luminescence arises only from the molecules of the fluorescent dye which have a high fluorescence quantum efficiency. Accordingly, by the addition of a fluorescent dye into the composition for the organic EL element, the luminescence spectrum of the luminescent layer becomes at the same time the spectrum of the fluorescent dye, whereby this method becomes also an effective means for changing the emitted color.

[0060] In this connection, it should be noted that what is meant here by the current quantum efficiency is a scale for considering the luminescence performance according to the luminescence function, and it is defined by the following expression.

$$\eta_E = \text{energy of emitted photon} / \text{input electrical energy.}$$

[0061] The changes in the maximum wavelength of light absorption induced by the doping of a fluorescent dye make it possible, for example, to emit the three primary colors of red, green and blue, thereby enabling to obtain a full color

display device.

[0062] Further, the doping of the fluorescent dye makes it possible to improve extremely the luminous efficiency of the EL element.

[0063] As for a fluorescent dye used for the red luminescent layer, laser dye DCM, rhodamine or a rhodamine derivative, perylene and the like can be used. These fluorescent dyes are soluble to solvents because they are low molecules, and have a high compatibility with PPV or the like, so that a luminescent layer with a good uniformity and good stability can be formed easily. As for examples of the rhodamine derivative fluorescent dyes, rhodamine B, rhodamine B base, rhodamine 6G, rhodamine 101 perchlorate can be mentioned. In this case, a mixture of two or more of them can be selectively used.

[0064] Further, as for a fluorescent dye used in the green luminescent layer, quinacridone, rubrene, DCJT and their derivatives can be mentioned. Since these fluorescent dyes are low molecules in the same manner as the fluorescent dyes to be used in the above-mentioned red luminescent layer, they are soluble to solvents and have a high compatibility with PPV or the like, so that the luminescent layer can be formed easily.

[0065] As for the fluorescent dye used in the blue luminescent layer, distyrylbiphenyl and its derivative can be mentioned. These fluorescent dyes are soluble to aqueous solutions in the same manner as the above-mentioned fluorescent dyes for the red luminescent layer, and have high compatibility with PPV or the like, so that the luminescent layer can be formed easily.

[0066] In addition, as for other fluorescent dyes that can be used in the blue luminescent layer, coumarin; and coumarin derivatives such as coumarin-1, coumarin-6, coumarin-7, coumarin 120, coumarin 138, coumarin 152, coumarin 153, coumarin 311, coumarin 314, coumarin 334, coumarin 337, coumarin 343 and the like can be mentioned.

[0067] Moreover, as for other luminescent materials that can be used in the blue luminescent layer, tetraphenylbutadiene (TPB) or TPB derivative, DPVBI and the like can be mentioned. Since these luminescent materials are also low molecules in the same manner as the fluorescent dyes for the red luminescent layer, they are soluble to solvents, and have high compatibility with PPV or the like, so that the luminescent layer can be formed easily.

[0068] These fluorescent dyes and luminescent materials as described above can be selectively used as a just one of them or as a mixture of two or more of them.

[0069] The structure of a head of the ink-jet system used in the manufacturing method of the organic EL element according to the present invention is shown in Fig. 10 and Fig. 11.

[0070] The head 10 for the ink-jet system is provided with, for example, a stainless steel nozzle plate 11 and a vibration plate 13, and they are coupled via partitioning members (reservoir plates) 15.

[0071] Between the nozzle plate 11 and the vibration plate 13, a liquid storage 21 and a plurality of spaces 19 are formed by means of the reservoir plates 15. The inside of the respective spaces 19 and the liquid storage 21 are filled with the composition according to the present invention, and the spaces 19 communicate with the liquid storage 21 through supply ports 23.

[0072] Further, a nozzle hole 25 is provided in the nozzle plate 11 for discharging the composition in a jet-form from the spaces 19. In the meantime, a hole 27 is formed in the vibration plate 13 for supplying the composition to the liquid storage 21.

[0073] Further, on a surface of the vibration plate 13 which is opposite to the other surface that faces with the spaces 19, piezoelectric elements 29 are attached at positions corresponding to the positions of the respective spaces 19.

[0074] Each of the piezoelectric elements 29 is positioned between a pair of electrodes 31. The piezoelectric element 29 is adapted to bend so as to protrude outward when energized, and at the same time, the vibration plate 13 to which the piezoelectric element 29 is attached is also bent outward together with the piezoelectric element 29. In this way, the volume of the space 19 is increased. With this result, a quantity of the composition corresponding to the increased volume flows into the space 19 from the liquid storage 21 through the supply port 23.

[0075] Next, when the piezoelectric element is de-energized, both the piezoelectric element 29 and the vibration plate 13 return to their original shapes. In this way, the space 19 also returns to its original volume, so that the pressure exerted to the composition within the space 19 goes up, whereby the composition is jetted out from the nozzle hole 25 toward the substrate.

[0076] In this connection, a water repellent layer 26 is formed at the peripheral part of the nozzle hole 25 in order to prevent the bend of the jetted direction of the composition and the clogging of the hole from occurring.

[0077] Namely, a water repellent layer 26 formed of, for example, a Ni-tetrafluoroethylene eutectoid plated layer is provided in the peripheral part of the nozzle hole 25 as shown in Fig. 11.

[0078] Using the head with the above construction, it is possible to form respective organic luminescent layers by discharging the compositions corresponding to, for example, the three primary colors red, blue, and green according to a predetermined pattern, thereby enabling to form the pixels.

[0079] In the manufacturing method of the organic EL element according to the present invention, compositions with the following characteristics can be used as organic luminescent materials for the ink-jet method.

[0080] It is preferable that the compositions have a contact angle of 30 to 170 degrees, and more preferably, 35 to

65 degrees, with respect to the material constituting the nozzle surface 251 of the nozzle provided in the head for the ink-jet system for discharging the composition. When the composition has the contact angle given in this range, it is possible to carry out a precise patterning by suppressing the bend in the jetted direction of the composition.

[0081] Namely, if the contact angle is less than 30 degrees, wettability of the composition with respect to the material constituting the nozzle surface increases, so that there is a case that the composition attaches asymmetrically to the periphery of the nozzle hole at the time of discharging the composition. In this case, an attraction acts between the composition attached to the nozzle hole and the composition to be discharged. This causes the discharge of the composition by a non-uniform force, which gives rise to a situation so-called "bend in the jetted direction" in which the composition is unable to reach the target position, and also to an increase in the occurrence frequency of the bend in the jetted direction. Meantime, if the contact angle exceeds 170 degrees, the interaction between the composition and the nozzle hole becomes a minimum and the shape of the meniscus at the tip of the nozzle is unstable, so that the control of the amount and the timings of discharge of the composition tends to be difficult.

[0082] In the above descriptions, what is meant here by the bend in the jetted direction refers to a situation in which, when the composition is discharged from the nozzle, the point of impact of a dot deviates from the target position by more than 50 μm . Further, the occurrence frequency of the bend in the jetted direction is defined as the time until the bend in the jetted direction occurs after a continuous discharge of the composition is started at the frequency of 7200Hz. The bend in the jetted direction is generated principally by such causes as the nonuniformity in the wettability of the nozzle hole and the clogging of the nozzle hole by the attachment of solid components of the composition. Such bend in the jetted direction can be eliminated by cleaning the head. In this connection, more frequent head cleaning is required for more frequency of occurrence of the bend in the jetted direction, and such a composition that arises the higher occurrence frequency can be said to a composition that deteriorates the manufacturing efficiency of the EL element by the ink-jet method. On the practical level, an occurrence frequency of the bend in the jetted direction is required to be more than 1000 seconds.

[0083] By preventing such bend in the jetted direction from occurring, it becomes possible to carry out a highly fine patterning with high precision.

[0084] Further, it is preferable that the viscosity of the composition is 1 to 20cp, and more preferably 2 to 4cp. If the viscosity of the composition is less than 1cp, the contents of the precursor and the fluorescent dye in the material are too small, so that the luminescent layer which is formed cannot exhibit luminescence power sufficiently. On the other hand, if it exceeds 20cp, it is impossible to discharge the composition smoothly from the nozzle, and it becomes difficult to carry out patterning unless otherwise such a change in the specification as the enlargement of the diameter of the nozzle hole is introduced. In addition, when the viscosity of the composition is high, precipitation of the solid components in the composition tends to occur, thus leading to an increased occurrence frequency of clogging of the nozzle hole.

[0085] Furthermore, it is preferable that the composition has the surface tension of 20 to 70 dyne/cm, and more preferably 25 to 40 dyne/cm. By restricting the surface tension to such a range, it is possible to suppress the bend in the jetted direction and suppress the occurrence frequency of the bend in the jetted direction to a low level, in the same manner as the case of the above-mentioned contact angle. If the surface tension is less than 20 dyne/cm, the wettability of the composition with respect to the material constituting the nozzle surface increases, which results in the occurrence of the bend in the jetted direction, and an increase in the occurrence frequency of the bend in the jetted direction, similar to the case of the contact angle. On the other hand, if it exceeds 70 dyne/cm, the shape of the meniscus at the tip of the nozzle is not stable, which results in the difficulty in the control of the amount and the timings of discharge of the composition.

[0086] Further, as for the composition of the organic luminescent material suitable for the manufacturing method of the organic EL element of this invention, it needs to satisfy the condition on the numerical range for at least one of the characteristics including the contact angle, the viscosity and the surface tension described above. In this connection, a composition which satisfies the conditions for the arbitrary combination of two characteristics is more preferable, and a composition which satisfies the conditions for all the characteristics is most preferable.

[0087] Fig. 2 shows a second embodiment of the manufacturing method of the organic EL element according to the present invention.

[0088] In this second embodiment, after formation of pixel electrodes 201, 202 and 203 and banks 205 on a transparent substrate 204, a red luminescent layer 206 and a green luminescent layer 207 are formed by using an ink-jet method in the same manner as the first embodiment.

[0089] This second embodiment is different from the first embodiment in the point that a hole injection and transfer layer 208 is formed on the pixel electrode 203 and then a blue luminescent layer 210 is laminated on the layer 208. By the lamination of the hole injection and transfer layer 208 with the blue luminescent layer, it becomes possible to promote the injection and transfer of the holes from the electrode to improve the luminous efficiency as mentioned above.

[0090] Thus, in the manufacturing method for the organic EL element according to the present invention, it is preferable to laminate a hole injection and transfer layer with at least one luminescent layer with a certain color. In this

way, it is possible to improve the luminous efficiency and to improve the stability of the thin film element itself.

[0091] In this case, at the vicinity of the interface between the luminescent layer and the hole injection and transfer layer which are laminated with each other, a part of the materials contained in either of layers may exist in the state of mutual impregnation and diffusing into the other layer.

[0092] It is preferable that the hole injection and transfer layer 208 is a non-luminescent layer. With this arrangement, it is possible to make a region of the blue luminescent layer 210 positioned above the pixel electrode 203 to be a luminescent portion, thereby enabling to fabricate a full color organic EL element more easily.

[0093] No particular limitation is imposed upon the forming method for such a hole injection and transfer layer 208, but for example, it is possible to form the layer by using the ink-jet method. In this way, it becomes possible to arrange the hole injection and transfer layer 208 precisely with a predetermined pattern.

[0094] As for examples of the material constituting the hole injection and transfer layer 208, aromatic diamine based compound such as TPD; MTDATA; quinacridone; bisstil anthracene derivative; PVK (polyvinyl carbazole); phthalocyanine based complex such as copper phthalocyanine; porphin based compound; NPD; TAD; polyaniline; and the like can be mentioned. Among these materials, PVK is particularly preferred. By using PVK, it becomes possible to form a non-luminescent hole injection and transfer layer.

[0095] Further, the organic EL element according to the present invention can be obtained by forming a blue luminescent layer 210 and a cathode 211 in the same way as the first embodiment. The materials constituting the blue luminescent layer 210 and the cathode 211 and the manufacturing method thereof are the same as those of the first embodiment.

[0096] Fig. 3 shows a third embodiment of the manufacturing method for the organic EL element according to the present invention.

[0097] In this third embodiment, after the formation of pixel electrodes 301, 302 and 303 and banks 305 on a transparent substrate 304, a red luminescent layer 306 and a green luminescent layer 307 are formed in the same manner as the first embodiment.

[0098] Next, a hole injection and transfer layer 308 is formed on the entire surface of the red luminescent layer 306, the green luminescent layer 307 and the pixel electrode 303. By laminating the hole injection and transfer layer 308 with the luminescent layers 306 and 307 in this way, it is possible to promote the injection and the transfer of the holes from the electrodes to improve the luminescence efficiency, as described in the above.

[0099] Further, by the same reason as in the above, it is preferable that the hole injection and transfer layer 308 is formed into a non-luminescent layer.

[0100] No particular limitation is imposed upon the forming method for the hole injection and transfer layer 308, and for example, ink-jet method, vacuum deposition method, dipping method, spin coating method, casting method, capillary method, roll coating method, bar coating method and the like can be mentioned. In this embodiment, it is to be noted that the hole injection and transfer layer can be formed using the vacuum deposition method. In this connection, as for the material constituting the hole injection and transfer layer 308, the same materials as those mentioned in the second embodiment can be used.

[0101] Further, by forming a blue luminescent layer 309 and a cathode 311 on the hole injection and transfer layer 308, the organic EL element according to the present invention can be obtained. The constituent material and the forming method of the cathode 311 are the same as those of the above-mentioned embodiments.

[0102] Fig. 4 shows a fourth embodiment of the manufacturing method for the organic EL element according to the present invention.

[0103] In this fourth embodiment, after the formation of pixel electrodes 801, 802 and 803 and banks 805 on a transparent substrate 804 in the same way as the first embodiment, luminescent layers 806, 807 and 808 are patterned on the pixel electrodes 801, 802 and 803, respectively, by the ink-jet method. In this way, the amount of the material to be discharged for the respective luminescent layers, the number of times of the discharge and the formation pattern of the luminescent layers, for example, can be adjusted easily and handily, so that the luminescent characteristics and film thickness and the like of the respective luminescent layers can be controlled easily.

[0104] In addition, an electron injection and transfer layer 811 is formed on the luminescent layers 806, 807 and 808. The electron injection and transfer layer 811 facilitates the injection of the electrons from the cathode, and contributes to the prevention of electrode extinction by keeping the luminescent portions away from the cathode to establish a better contact with the cathode. As for the electron injection and transfer layer 811, aluminum quinolynol complex to which the doping is not carried out can be used. This electron injection and transfer layer 811 can be formed by means of a vacuum deposition method.

[0105] In this connection, the forming method for the electron injection and transfer layer 811 is not limited to this method, and for example, the ink-jet method, vacuum deposition method, dipping method, spin coating method, casting method, capillary method, roll coating method, bar coating method or the like can be used.

[0106] Further, the organic EL element according to the present invention can be obtained by forming a cathode 813 on top of it. The constituent material and the formation method of the cathode 813 are the same as those of the above-

mentioned embodiments.

[0107] Fig. 5 shows a fifth embodiment of the manufacturing method of the organic EL element according to the present invention.

[0108] In this fifth embodiment, pixel electrodes 801, 802 and 803 are first formed on a transparent substrate 804 in the same manner as the first embodiment. Then, a hole injection and transfer layer 815 which is for example made of PVK is formed on the entire surfaces of the pixel electrodes by means of, for example, a spin coating method. Accordingly, since the hole injection and transfer layer 815 in this embodiment can be formed by means of coating without need of patterning, it is possible to increase manufacturing efficiency.

[0109] No particular limitation is imposed upon the forming method for the hole injection and transfer layer 815, and for example, ink-jet method, vacuum deposition method, dipping method, spin coating method, casting method, capillary method, roll coating method, bar coating method and the like can be used.

[0110] Further, from the same reason described above with reference to the other embodiments, it is preferred that the hole injection and transfer layer 815 is formed into a non-luminescent layer.

[0111] On top of the hole injection and transfer layer 815, luminescent layers 806, 807 and 808 are formed. In this regard, it is preferred that among these luminescent layers, at least one luminescent layer for a certain color is formed by patterning using the ink-jet method carried by the ink-jet device 809.

[0112] Then, by forming a cathode 813 on top of the luminescent layers, an organic EL element according to the present invention can be obtained. The structural material for the cathode 813 and the manufacturing method thereof are the same as those of the other embodiment described above.

[0113] According to this fifth embodiment, no bank is formed. However, by using this manufacturing method, the coating of the luminescent layers for the primary colors R, G and B can be carried out correctly and precisely, thus leading to improvement of manufacturing efficiency. In this regard, it is to be noted that the manufacturing method of this embodiment can be also applied to the case where banks are provided to form respective pixels like the previous embodiments.

[0114] The organic EL element of the present invention can be manufactured according to the manufacturing methods described above with reference to the embodiments. However, the present invention is not limited to the structures provided by these methods, and the following structures can be adopted, for instance.

[0115] Fig. 15 is a partial cross-sectional view which shows other embodiment of an organic EL element according to the present invention.

[0116] The organic EL element of this embodiment has a construction in which a reflection layer 62, a transparent conductive film (ITO film) 63, a hole injection and transfer layer 64, an organic luminescent layer 65, a metal layer 66 and a transparent conductive layer (ITO film) 67 are laminated on a transparent substrate 61 in this order. Hereinbelow, the materials and the manufacturing methods of the respective layers (films) are described, in which a description is made only for the differences from the previous embodiments and the common explanation is omitted.

[0117] In the organic EL element according to this embodiment, on the transparent substrate 61, the reflection layer 62 which is made from a metal thin film such as Al is provided directly.

[0118] The metal layer 66 which is laminated onto the luminescent layer 65 as a cathode is extremely thin (approximate to 10 to 50 Å), so that the metal layer has a light permeability so as to pass emitted light from the luminescent layer 65 therethrough. On the other hand, since the metal layer is extremely thin, its value of resistance is high and therefore its conductivity is insufficient. Therefore, the metal layer can not sufficiently exhibit function as the cathode. For this reason, the transparent conductive film (ITO film) 67 is laminated onto the metal layer 66. In this connection, it is to be noted that such a metal layer 66 can be made from Al - Li alloy or the like for example, and it can be formed using the vacuum deposition method, sputtering method or the like.

[0119] By using the above described construction, light which is converted in the luminescent layer 65 from a current which has been injected from the electrodes is transmitted in the direction indicated by the arrow in the drawing. With this result, it becomes possible to take out the light without passing through the transparent substrate 61, so that a display with a higher brightness becomes possible.

[0120] Fig. 7 is an illustration which shows an embodiment of an organic EL display device according to the present invention.

[0121] In this embodiment, a bus line (gate line) 511 made of Al is formed on a glass plate 501 by means of a photolithography patterning method, and a thin film transistor (not shown in the drawing) is formed thereon to constitute the ITO transparent pixel electrode 504 and the like. Then, as is the same manner as the first embodiment, a red luminescent layer 502 and a green luminescent layer 503 are formed by means of the ink-jet method, and then a blue luminescent layer 505 is formed by means of the vacuum deposition method. Thereafter, a cathode 506 is formed by means of the vacuum deposition method, thereby constructing the organic EL element same as the first embodiment described above.

[0122] In addition, a protective base material 507 is stuck onto the transparent substrate 501 in a fixed manner by means of a peripheral seal 509.

[0123] Next, this assembly is placed in an inert gas atmosphere such as argon gas or the like, and thereby introducing the inert gas inside thereof from a seal opening 513 and then the seal opening 513 is sealed with a seal member 508. By filling the inside of the assembly with the inert gas 512 and then sealing it, as described above, it becomes possible to protect the organic EL element from external contamination such as moisture or environmental changes, thereby enabling to maintain the luminescent characteristics of the organic EL display device. In this case, it is preferred that the seal member 508 is formed from a material through which the inert gas 512 does not penetrate.

[0124] A silver paste 510 has a function that realizes a contact between the cathode 506 and the gate line 511 on the element.

[0125] Gate lines 511 are provided to control ON and OFF of the thin film transistors (TFT), which are provided in the respective display pixels, in each line of the pixels in order to select pixels to be displayed. Upon writing, potential of the gate line for one line of pixels is turned into a selected level, thereby bringing the TFTs on this line into a conductive state. At this time, by supplying picture signals for the corresponding pixels from the source electrode wires of the respective lines (not shown in the drawing), the voltages of the picture signals are applied to the pixel electrodes through the TFTs, thereby enabling to charge the potentials to the pixels to a level of a signal voltage and then discharge them.

[0126] Fig. 8 is an illustration which shows other embodiment of an active matrix type organic EL display device using the organic EL element according to the present invention. This organic EL display device of this embodiment includes an pixel arrangement comprised of a plurality of luminescent pixels which are arranged in a matrix form and which are formed into any one of R, G and B luminescent elements.

[0127] As shown in this figure, on the substrate (not shown), there are provided signal lines (signal electrodes) 601 and gate lines (gate electrodes) 602 which are arranged in a matrix form so as to be orthogonal to each other. Further, in each of the pixels, a thin film transistor (TFT) 604 which is connected to both the signal line 601 and the gate line 602 is provided, and a luminescent layer 605, 606 which is formed of the organic EL element and connected to the TFT is laminated on the TFT. In this case, at least one luminescent layer for any one of colors R, G, B is formed by means of the ink-jet method.

[0128] Fig. 9 is a sectional view which shows one example of the manufacturing method of the active matrix type organic EL display device according to the present invention.

[0129] First, on a transparent substrate 904, predetermined thin film transistors 915 as well as gate lines and signal lines (not shown) and the like are formed. Next, on respective pixel electrodes (ITO) 901, 902, 903 which are respectively provided with prescribed functional elements such as the thin film transistors 915, hole injection and transfer layers 911 are formed so as to cover the respective pixel electrodes. As for the hole injection and transfer type material, the same materials that are discussed in this specification with reference to the previous embodiments can be used. Further, the method of forming the hole injection and transfer layer 911 is not limited to a specific method, and it is possible to form the layer by means of any method described above.

[0130] Further, respective luminescent layers 906 (red), 907 (green) and 908 (blue) are formed by patterning. In the formation of these luminescent layers, at least one layer for one color is formed by the ink-jet method using an ink-jet device 910.

[0131] Finally, a reflection electrode 913 is formed, thereby completing the organic EL display device according to the present invention. As for the reflection electrode 913, Mg - Ag electrode having a thickness of about 0.1 to 0.2 μm or the like is formed, for instance.

[0132] In the above-mentioned embodiment concerning the active matrix type organic EL display device according to the present invention, a thin film transistor is used as a switching element, but the present invention is not limited thereto. Other switching elements and two-terminal element such as MIM can be used. Further, the display device may be configured into a passive drive type or a static drive type (static image, segment display).

[0133] Furthermore, the number of the switching element is not limited to one per one pixel. A plurality of switching elements may be provided per one pixel.

[0134] Fig. 12 shows an embodiment of an organic EL display device in which a plurality of switching elements are provided per one pixel. In this embodiment, a switching type thin film transistor 142 carries out a role that transmits the potential at a signal electrode 132 to a current thin film transistor 143 in response to the potential at a scanning electrode 131, and the current thin film transistor 143 carries out a role that controls electrical connection between the common electrode 133 and the pixel electrode 141.

[0135] Next, referring to the drawings, a description is made with regard to an embodiment of a passive matrix type (simple matrix type) organic EL display device using the organic EL element according to the present invention.

[0136] Fig. 13 is a perspective view which roughly shows a structure of the organic EL display device according to the present invention.

[0137] As shown in the drawings, in the organic EL display device of this embodiment, a scanning electrode 53 and a signal electrode 54 which are formed into an elongated strip, respectively, are arranged outside the organic EL element 52 so that scanning lines extending from the scanning electrode 53 and the signal lines extending from the signal electrode 54 are orthogonal to each other through the organic EL element.

[0138] Such a passive matrix type display device is driven by selecting scanning lines of the scanning electrode 53 in a pulsed manner in a sequential order while a voltage is applied to signal lines of the signal electrode 54 corresponding to pixels to be displayed on the scanning line. Such selection of the lines is carried out by a controller 55.

[0139] In this connection, it should be noted that in a case of the passive drive type display device, it is necessary that a cathode is patterned so as to be separate forms to correspond to each of lines. For example, when a thin cathode having a thickness of about $0.2 \mu m$ is formed according to the third embodiment, such separate forms of the cathode can be automatically obtained since the cathode is separated by the banks.

[0140] Such a cathode is formed by the pattern formation performed by a masking deposition method or a laser cutting method, for instance.

[0141] Fig. 14 is a diagram which shows one example of wave forms of driving voltages applied to the scanning electrode 13 and signal electrode 14, respectively. The wave forms shown in the drawing are determined so as to be able to apply a voltage V_s which is sufficient to luminescence to selected pixels. Further, the brightness of a pixel to be displayed is controlled through the width of the pulse from the signal electrode 14 that has been determined so as to meet with a gray scale of the brightness to be displayed. On the other hand, a voltage V_n which is lower than a luminescent threshold voltage is applied to respective non-selected pixels.

[0142] In Fig. 14, T_f shows a scanning timing. In this case, the scanning signal is driven by a pulse having a duty ratio of 1/100. In this connection, it has been confirmed that the luminescence of the blue luminescent layer 808 of the organic EL display device comprised of the organic EL elements of the fourth embodiment was a brightness of 100 cd/m^2 at a driving voltage of 20V.

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EXAMPLES

<Manufacturing of Organic EL Elements>

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(Example 1)

[0143] As shown in Fig. 1, on the glass substrate 104, ITO transparent pixel electrodes 101, 102 and 103 were formed by means of photolithography so as to form a pattern having a pitch of $100 \mu m$ and a thickness of $0.1 \mu m$.

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[0144] Then, the spaces between the ITO transparent pixel electrodes were buried, and then banks 105 which act not only as a light cut-off layer but also an ink drop preventing wall were formed by photolithography. In this case, the banks 105 were designed so as to have a width of $20 \mu m$ and a thickness of $2.0 \mu m$.

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[0145] Further, after the pattern formation with red and green luminescent materials shown in Table 1 and Table 2 which were jetted from the head 110 of the ink-jet device 109, they were undergone heat treatment under a nitrogen atmosphere for hours to polymerize the precursors in the compositions of the materials, thereby forming luminescent layers 106 (red) and 107 (green).

[0146] Then, by carrying out a vacuum deposition of aluminum quinolynol complex to which perylene condensed aromatic was added as a dopant, a blue luminescent layer 108 of the electron injection and transfer type having a thickness of $0.1 \mu m$ was formed.

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[0147] At the last, a Mg - Ag electrode 113 having a thickness of $0.8 \mu m$ was formed as a cathode using a vacuum deposition method to obtain an organic EL element.

(Example 2)

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[0148] In the same manner as Example 1, ITO transparent pixel electrodes 201, 202, 203 were formed on a glass substrate 204 as shown in Fig. 2. Thereafter, the spaces between the ITO transparent pixel electrodes were buried and then resists (partitioning walls) 205 made of a light-sensitive polyimide and functioning not only as a light cut off layer but also an ink drop preventing wall were formed.

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[0149] Then, after coating and pattern formation of red and green luminescent materials shown in Table 1 and Table 2, respectively, by using an ink-jet device 209 in the same way as the Example 1, they were undergone heat treatment under a nitrogen atmosphere for four hours to polymerize the precursors in the compositions of the materials, thereby forming luminescent layers 206 (red) and 207 (green).

[0150] Next, a hole injection and transfer layer made of polyvinyl carbazole (PVK) was patterned on the transparent pixel electrode 203 by means of the ink-jet device 209. Then, a blue luminescent layer 210 was formed by coating the pyrazoline dimer on top of the hole injection and transfer layer.

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[0151] Finally, an Al - Li electrode 211 having the thickness of $0.8 \mu m$ was formed as the cathode by the deposition method, and thereby the organic EL element was manufactured.

(Example 3)

[0152] First, ITO transparent pixel electrodes 801, 802 and 803 and banks 805 were formed on a glass substrate 804 as shown in Fig. 4 in the same way as Example 1.

[0153] Next, an organic hole injection and transfer type material was mixed in the luminescent materials shown in Table 1 and Table 2 to form luminescent layers 806 (red), 807 (green) and 808 (blue) by using an ink-jet device 809.

[0154] Next, the vacuum deposition was carried out using the aluminum quinolynol complex to which the doping was not carried out to form an electron injection and transfer layer 811 having the thickness of 0.1 μm .

[0155] Finally, an Al - Li electrode 813 having the thickness of 0.2 μm was formed as the cathode by the deposition method, and thereby the organic EL element was manufactured.

(Example 4)

[0156] In the same way as Example 1, ITO transparent pixel electrodes 301, 302 and 303 and banks 305 were formed on a glass substrate 304 as shown in Fig. 3.

[0157] Next, after coating and pattern formation with red and green luminescent materials shown in Table 1 and Table 2, respectively, by using an ink-jet device 310 in the same way as Example 1, they were undergone heat treatment under a nitrogen atmosphere for four hours to polymerize the precursors in the compositions of the materials, thereby forming luminescent layers 306 (red) and 307 (green).

[0158] Next, a hole injection and transfer layer 308 made of polyvinyl carbazole (PVK) was formed on the entire surfaces of the luminescent layers 306, 307 and the transparent electrode 303 by means of the coating method.

[0159] Then, a blue luminescent layer 309 made of a distyryl derivative was formed on the hole injection and transfer layer 308 by means of the vacuum deposition method.

[0160] Finally, an Al - Li electrode 311 having the thickness of 0.8 μm was formed as the cathode by the deposition method, and thereby the organic EL element was manufactured. In this case, as described above, the cathode 311 was automatically separated and then insulated by the formation of the banks 304, the cathode was brought into a condition that is was patterned so as to correspond to the respective pixels 301, 302 and 303.

(Example 5)

[0161] First, in the same way as Example 1, ITO transparent electrodes 801, 802 and 803 and banks 805 were formed on a glass substrate 804 as shown in Fig. 4.

[0162] Then, after coating and pattern formation with the red, green and blue luminescent materials by discharging polymeric organic luminescent materials shown in Table 1 and Table 2, respectively, using the ink-jet device 809, they were undergone heat treatment under a nitrogen atmosphere at 150°C for four hours to polymerize the precursors in the compositions of the materials, thereby forming luminescent layers 806 (red), 807 (green) and 808 (blue).

[0163] Next, the vacuum deposition was carried with the aluminum quinolynol complex to which the doping was not carried out to form the electron transfer layer 811 having the thickness of 0.1 μm .

[0164] Finally, an Al - Li electrode 812 having the thickness of 0.8 μm was formed as the cathode by the vacuum deposition, so that the organic EL element was manufactured.

<Evaluation of the Luminescence Characteristics and the Film Characteristics of the Luminescent Layers>

[0165] The luminescence characteristics and the film characteristics of the luminescent layers of the organic EL elements which were manufactured in Examples 1 to 5 described above were evaluated according to the following methods.

1. Luminescence Starting Voltage

[0166] A prescribed voltage was applied to the element, and the applied voltage at which a luminance of 1 cd/m^2 is observed was defined as the luminescence starting voltage [V_{th}].

2. Luminescence Life

[0167] The initial luminance after applying a stabilization treatment was set to 100%, and the changes in the luminance of the EL element were measured when subjecting it to continuous luminescence through supply of a constant current of standard waveform, wherein the luminescence life is defined as the time until the luminance drops to 50% of the initial luminance.

[0168] In this case, the drive conditions for this experiment were set at 40°C for room temperature, 23% for humidity and 20 mA/cm² for current density.

3. Luminance (Brightness)

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[0169] The luminance was measured, in which the current was set to 20 mA/cm².

4. Wavelength at Maximum Absorption

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[0170] The wavelength at maximum absorption for each luminescent layer was measured.

5. Stability in Film Formation

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[0171] After heating the luminescent layer at 200°C for 60 minutes, conditions for occurrence of defects such as cracks and deformation in the respective luminescent layers were observed by a microscope.

[0172] The results of the evaluation were classified according to the following marks.

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- Ⓐ Extremely favorable
- Ⓑ Favorable
- Ⓒ Unsatisfactory

[0173] The results of the evaluation are shown in Table 3 and Table 4.

[0174] As indicated in Table 3 and Table 4, the luminescent layers in Examples 1 to 5 have excellent luminescence characteristics and excellent film characteristics. In particular, when the luminescent layers were formed of polymer organic compounds, no defects were observed in the luminescent layers, and extremely favorable thin films were obtained.

[0175] In the above, the compositions for the organic EL elements and the manufacturing methods for the organic EL elements according to the present invention have been described according to the embodiments that are illustrated. However, the present invention is not limited to these embodiments, and for example, there may be inserted in the manufacturing processes for providing any intermediate functional layers between the respective layers. Further, the fluorescent dyes which are added for changing the luminescence characteristics are not limited to those described above.

[0176] Further, a layer made of, for example, 1,2,4-triazole derivative (TAZ) may be provided as a buffer layer between the respective layers, thereby enabling to more improve the luminance, luminescence life and the like.

[0177] Furthermore, the manufacturing method for the organic EL elements according to the present invention may include a further process in which surface treatment such as plasma, UV treatment, coupling or the like are applied to the surface of the resin resists, the pixel electrodes and the underlying layers in order to facilitate the sticking of the EL materials. Moreover, it is possible to apply the manufacturing method for the organic EL element of the present invention to the manufacturing method for the inorganic EL element.

[0178] The organic EL display device according to the present invention may be applied to the low information field, such as segment display and still image display of whole surface simultaneous luminescence, for example, display of pictures, characters, labels, or may be utilized as a light source having point, line, or surface shape.

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[0179] As described in the above, according to the manufacturing method of the organic EL element of the present invention, it is possible to explore rational design of the EL luminescent elements through a wide ranging selection of the luminescent materials. For example; through arbitrary combinations of the luminescent materials and fluorescent dyes, it is possible to obtain wide variety of display lights.

[0180] Further, by using the organic luminescent materials, it is possible to obtain the diversified designs of the EL element having high luminance and long life.

[0181] Furthermore, by carrying out the pattern forming and arrangement of the luminescent layer for at least one color, the hole injection and transfer layer and the electron injection and transfer layer by means of the ink-jet method, it is possible to set arbitrarily and precisely the size and the pattern of the luminescent elements.

[0182] When a precursor, which can be conjugated (form a film) by thermosetting is used as a luminescent material, the latitude in the setting of conditions such as viscosity can be expanded, and the adjustment of the conditions suitable as a discharge liquid for the ink-jet method can be facilitated.

[0183] Further, according to the manufacturing method for the organic EL element of the present invention, conditions

such as the film thickness, the number of dots and the like can be adjusted arbitrarily, so that it is possible to control readily the luminescence characteristics of the luminescent layers.

[0184] Furthermore, according to the ink-jet method, it is possible to move freely the head on the transparent substrate, thereby enabling to form an element with an arbitrary size without restricting the dimensions of the substrate. Moreover, since required amounts of materials can be arranged at required locations, it is possible to maximally exclude the uselessness of waste liquid or the like. In this way, manufacturing of a full color display device with large screen size becomes possible at a low cost.

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Table 1

		Luminescent Layer			Layer between Layers
		Red	Green	Blue	
Example 1	Luminescent Material	CN-PPV Precursor	PPV Precursor	Aluminum Quinolinol Complex	—
	Forming Method	Ink-Jet System	Ink-Jet System	Vacuum Deposition Method	
Example 2	Luminescent Material	CN-PPV Precursor	PPV Precursor	Pyrazoline Dimer	PVK (Hole Injection Layer)
	Forming Method	Ink-Jet System	Ink-Jet System	Coating Method	
Example 3	Luminescent Material	2-13':4'-dihydroxyphenyl-3,5,7-trihydroxy-1-benzopyrylium perchlorate	2,3,6,7-tetrahydro-11-oxo-1H,5H,11H-(1)benzopyrano[6,7,8-i,j]-quinolizine-10-carboxylic acid	2,3,6,7-tetrahydro-9-methyl-11-oxo-1H,5H,11H-(1)benzopyrano[6,7,8-i,j]-quinolizine	Ink-Jet System
			1,1-bis-(4-N,N-di tolylaminophenyl) cyclohexane (Hole injection layer material)	1,1-bis-(4-N,N-di tolylaminophenyl) cyclohexane (Hole injection layer material)	
Example 4	Luminescent Material	CN-PPV Precursor	Ink-Jet System	Distyryl Derivative	PVK (Hole Injection Layer)
Example 5	Luminescent Material	PPV Precursor	Ink-Jet System	Vacuum Deposition Method	—

Table 2

Physical Properties of Composition for El. Element		Viscosity [cp]	Surface Tension [dyne/cm]	Contact Angle [°]
Example 1	Red	3. 77	32. 9	54. 4
	Green	3. 72	32. 8	59. 0
	Blue	—	—	—
Example 2	Red	3. 70	32. 6	55. 6
	Green	7. 73	33. 1	59. 8
	Blue	3. 88	33. 3	60. 0
Example 3	Red	4. 85	27. 8	47. 8
	Green	5. 31	25. 6	45. 6
	Blue	4. 52	28. 2	40. 3
Example 4	Red	3. 78	33. 5	60. 1
	Green	3. 75	32. 1	59. 7
	Blue	—	—	—
Example 5	Red	3. 80	33. 1	55. 0
	Green	3. 75	32. 9	59. 1
	Blue	3. 91	33. 2	60. 2

Table 3

	Luminescence Starting Voltage [V _{th}]			Luminescence Life [hr]			Luminance [cd/m ²]			Wavelength at Maximum Absorption [nm]		
	R	G	B	R	G	B	R	G	B	R	G	B
Example 1	2. 0	2. 2	3. 1	8000	8000	8000	210	230	200	600	500	400
Example 2	1. 7	1. 8	3. 2	10000	10000	9000	230	230	180	600	500	410
Example 3	4. 0	3. 5	3. 8	4000	5000	4000	150	180	100	580	510	420
Example 4	1. 7	1. 8	2. 2	10000	10000	10000	250	250	200	600	530	480
Example 5	3. 0	3. 2	5. 0	5000	5000	5000	200	200	200	590	530	420

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Stability in Film Formation	B	○	○	○	○	○
	G	○	○	○	○	○
	R	○	○	○	○	○
	Example 1	Example 2	Example 3	Example 4	Example 5	

Claims

25 1. A method of manufacturing an organic EL element, comprising:

30 forming first electrodes on or above a transparent substrate;
forming a luminescent layer on each of the first electrodes or a layer formed on or above each of the first electrodes by discharging a liquid composition including an organic emitting material by means of an ink jet method;

35 forming a second electrode on or above the luminescent layers; and
disposing a protective material on or above the second electrode.

40 2. A method of manufacturing an organic EL element as claimed in claim 1, wherein the organic emitting material is a polymer organic compound.

45 3. A method of manufacturing an organic EL element as claimed in claim 2, wherein the polymer organic compound is a material having functions of hole injection and hole transfer.

50 4. A method of manufacturing an organic EL element as claimed in claim 2, wherein the polymer organic compound is a polyparaphenylene vinylene or its derivative or a copolymer which contains at least either one of these compounds.

55 5. A method of manufacturing an organic EL element as claimed in claim 1, wherein three types of luminescent layers having three different colours are formed, and at least two types of luminescent layers in the three types of luminescent layers are formed by patterning by means of the ink-jet method.

60 6. A method of manufacturing an organic EL element as claimed in claim 5, wherein said three colours include red, green and blue, and the red luminescent layer and the green luminescent layer are formed by patterning by means of the ink-jet method.

65 7. A method of manufacturing an organic EL element as claimed in claim 6, wherein the blue luminescent layer (108) is formed by a vacuum deposition method.

70 8. A method of manufacturing an organic EL element as claimed in claim 7, wherein the blue luminescent layer (108) is made of a material having functions of electron injection and electron transfer.

9. A method of manufacturing an organic EL element as claimed in claim 1, wherein at least one luminescent layer is laminated onto a hole injection and transfer layer.
- 5 10. A method of manufacturing an organic EL element as claimed in claim 1, further comprising the step of forming on or above said transparent substrate electrodes for driving the respective pixels.
11. A method of manufacturing an organic EL element as claimed in claim 1, wherein said first electrodes are formed as transparent first electrodes.
- 10 12. An organic EL device, comprising:
 - a transparent substrate;
 - first electrodes provided on or above the transparent substrate;
 - 15 a luminescent layer formed of an organic emitting material on or above each of the first electrodes, an edge of the luminescent layer being positioned within an area occupied by the respective first electrode;
 - a second electrode on or above the luminescent layers; and
 - a protective film formed on or above the second electrode.
13. An organic EL device as claimed in claim 12, wherein the organic compound is a polymer organic compound.
- 20 14. An organic EL device as claimed in claim 13, wherein the polymer organic compound is a material having functions of hole injection and hole transfer.
- 15 15. An organic EL device as claimed in claim 13, wherein the polymer organic compound is a poly(4-phenylene vinylene) or its derivative or a copolymer which contains at least either one of these compounds.
- 25 16. An organic EL device as claimed in claim 12, wherein three types of luminescent layers having three different colours are formed, and at least two types of luminescent layers in the three types of luminescent layers are formed by patterning by means of an ink-jet system.
- 30 17. An organic EL device as claimed in claim 16, wherein said three colours include red, green and blue, and the red luminescent layer and the green luminescent layer are patterned by means of the ink-jet system.
18. An organic EL device as claimed in claim 17, wherein the blue luminescent layer is formed by a vacuum deposition method.
- 35 19. An organic EL device as claimed in claim 18, wherein the blue luminescent layer is made of a material having functions of electron injection and electron transfer.
- 40 20. An organic EL device as claimed in claim 12, wherein at least one luminescent layer is laminated onto an electron injection and transfer layer.
21. An organic EL device as claimed in claim 12, wherein said first electrodes are formed as transparent first electrodes.

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Patentansprüche

1. Verfahren zur Herstellung eines organischen EL-Elements, umfassend:
 - 50 Ausbilden von ersten Elektroden auf oder über einem transparenten Substrat;
 - Ausbilden einer Lumineszenzschicht auf jeder der ersten Elektroden oder einer Schicht, die auf oder über jeder der ersten Elektroden ausgebildet worden ist, durch Abgeben einer flüssigen Zusammensetzung, die ein organisches emittierendes Material enthält, mittels eines Tintenstrahlverfahrens;
 - 55 Ausbilden einer zweiten Elektrode auf oder über den Lumineszenzschichten; und
 - Aufbringen eines Schutzmaterials auf oder über der zweiten Elektrode.
2. Verfahren zur Herstellung eines organischen EL-Elements nach Anspruch 1, bei dem das organische emittierende Material eine organische Polymerzusammensetzung ist.

3. Verfahren zur Herstellung eines organischen EL-Elements nach Anspruch 2, bei dem die organische Polymerzusammensetzung ein Material ist, das Funktionen einer Lochinjektion und einer Lochübertragung aufweist.
4. Verfahren zur Herstellung eines organischen EL-Elements nach Anspruch 2, bei dem die organische Polymerzusammensetzung ein Polyparaphenylen-Vinylen oder dessen Derivat oder ein Copolymer ist, das wenigstens eine dieser Zusammensetzungen enthält.
5. Verfahren zur Herstellung eines organischen EL-Elements nach Anspruch 1, bei dem drei Typen von Lumineszenzschichten mit drei verschiedenen Farben ausgebildet werden, wobei wenigstens zwei Typen von Lumineszenzschichten in den drei Typen von Lumineszenzschichten durch Musterung mittels des Tintenstrahlverfahrens ausgebildet werden:
6. Verfahren zur Herstellung eines organischen EL-Elements nach Anspruch 5, bei dem die drei Farben Rot, Grün und Blau enthalten, wobei die rote Lumineszenzschicht und die grüne Lumineszenzschicht durch Musterung mittels des Tintenstrahlverfahrens ausgebildet werden.
7. Verfahren zur Herstellung eines organischen EL-Elements nach Anspruch 6, bei dem die blaue Lumineszenzschicht (108) mittels eines Vakuumabscheidungsverfahrens ausgebildet wird.
8. Verfahren zur Herstellung eines organischen EL-Elements nach Anspruch 7, bei dem die blaue Lumineszenzschicht (108) aus einem Material gefertigt wird, das Funktionen der Elektroneninjektion und der Elektronenübertragung aufweist.
9. Verfahren zur Herstellung eines organischen EL-Elements nach Anspruch 1, bei dem wenigstens eine Lumineszenzschicht auf einer Lochinjektions- und -übertragungsschicht laminiert wird.
10. Verfahren zur Herstellung eines organischen EL-Elements nach Anspruch 1, das ferner den Schritt des Ausbildens von Elektroden auf oder über dem transparenten Substrat zum Ansteuern der jeweiligen Pixel umfasst.
11. Verfahren zur Herstellung eines organischen EL-Elements nach Anspruch 1, bei dem die ersten Elektroden als transparente erste Elektroden ausgebildet werden:
12. Organische EL-Vorrichtung, umfassend:
 - 35 ein transparentes Substrat;
 - erste Elektroden, die auf oder über dem transparenten Substrat vorgesehen sind;
 - eine Lumineszenzschicht, die aus einem organischen emittierenden Material auf oder über jeder der ersten Elektroden ausgebildet ist, wobei eine Kante der Lumineszenzschicht innerhalb einer Fläche angeordnet ist, die von der jeweiligen ersten Elektrode belegt ist;
 - 40 eine zweite Elektrode auf oder über den Lumineszenzschichten; und
 - einen Schutzfilm, der auf oder über der zweiten Elektrode ausgebildet ist.
13. Organische EL-Vorrichtung nach Anspruch 12, bei der das organische emittierende Material eine organische Polymerzusammensetzung ist.
- 45 14. Organische EL-Vorrichtung nach Anspruch 13, bei der die organische Polymerzusammensetzung ein Material ist, das Funktionen einer Lochinjektion und einer Lochübertragung aufweist.
15. Organische EL-Vorrichtung nach Anspruch 13, bei der die organische Polymerzusammensetzung ein Polyparaphenylen-Vinylen oder dessen Derivat oder ein Copolymer ist, das wenigstens eine dieser Zusammensetzungen enthält.
- 50 16. Organische EL-Vorrichtung nach Anspruch 12, bei der drei Typen von Lumineszenzschichten mit drei verschiedenen Farben ausgebildet werden, wobei wenigstens zwei Typen von Lumineszenzschichten in den drei Typen von Lumineszenzschichten durch Musterung mittels des Tintenstrahlverfahrens ausgebildet werden.
17. Organische EL-Vorrichtung nach Anspruch 16, bei der die drei Farben Rot, Grün und Blau enthalten, wobei die rote Lumineszenzschicht und die grüne Lumineszenzschicht durch Musterung mittels des Tintenstrahlsystems

ausgebildet werden.

18. Organische EL-Vorrichtung nach Anspruch 17, bei der die blaue Lumineszenzschicht mittels eines Vakuumabscheidungsverfahrens ausgebildet wird.
- 5 19. Organische EL-Vorrichtung nach Anspruch 18, bei der die blaue Lumineszenzschicht aus einem Material gefertigt wird, das Funktionen der Elektroneninjektion und der Elektronenübertragung aufweist.
- 10 20. Organische EL-Vorrichtung nach Anspruch 12, bei der wenigstens eine Lumineszenzschicht auf einer Lochinjektions- und -übertragungsschicht laminiert ist.
- 15 21. Organische EL-Vorrichtung nach Anspruch 12, bei der die ersten Elektroden als transparente erste Elektroden ausgebildet sind.

Revendications

1. Procédé de fabrication d'un élément organique EL, comprenant :
 - 20 la formation de premières électrodes sur ou au-dessus d'un substrat transparent ;
 - la formation d'une couche luminescente sur chacune des premières électrodes ou d'une couche formée sur ou au-dessus de chacune des premières électrodes en déchargeant une composition liquide comportant une matière émettrice organique au moyen d'un procédé à jet d'encre ;
 - 25 la formation d'une seconde électrode sur ou au-dessus des couches luminescentes ; et
 - le dépôt d'une matière de protection sur ou au-dessus de la seconde électrode.
2. Procédé de fabrication d'un élément organique EL selon la revendication 1, dans lequel la matière émettrice organique est un composé organique polymère.
- 30 3. Procédé de fabrication d'un élément organique EL selon la revendication 2, dans lequel le composé organique polymère est une matière ayant des fonctions d'injection de trous et de transfert de trous.
4. Procédé de fabrication d'un élément organique EL selon la revendication 2, dans lequel le composé organique polymère est un vinylène polyparaphénylène ou son dérivé ou un copolymère qui contient au moins l'un quelconque 35 de ces composés.
5. Procédé de fabrication d'un élément organique EL selon la revendication 1, dans lequel trois types de couches luminescentes ayant trois couleurs différentes sont formés, et au moins deux types de couches luminescentes parmi les trois types de couches luminescentes sont formés par une formation de motifs au moyen du procédé à jet d'encre.
6. Procédé de fabrication d'un élément organique EL selon la revendication 5, dans lequel lesdites trois couleurs comprennent le rouge, le vert et le bleu, et la couche luminescente rouge et la couche luminescente verte sont formées par une formation de motifs au moyen du procédé à jet d'encre.
- 45 7. Procédé de fabrication d'un élément organique EL selon la revendication 6, dans lequel la couche luminescente bleue (108) est formée par un procédé de dépôt sous vide.
8. Procédé de fabrication d'un élément organique EL selon la revendication 7, dans lequel la couche luminescente bleue (108) est faite d'une matière ayant les fonctions d'injection d'électrons et de transfert d'électrons.
9. Procédé de fabrication d'un élément organique EL selon la revendication 1, dans lequel au moins une couche luminescente est laminée sur une couche de transfert et d'injection de trous.
- 55 10. Procédé de fabrication d'un élément organique EL selon la revendication 1, comprenant de plus l'étape de formation sur ou au-dessus desdites électrodes de substrat transparent pour piloter les pixels respectifs.
11. Procédé de fabrication d'un élément organique EL selon la revendication 1, dans lequel lesdites premières électrodes

trodes sont formées en tant que premières électrodes transparentes.

12. Dispositif organique EL, comprenant :

5 un substrat transparent ;
des premières électrodes disposées sur ou au-dessus du substrat transparent ;
une couche luminescente formée d'une matière émettrice organique sur ou au-dessus de chacune des premières électrodes, un bord de la couche luminescente étant positionné à l'intérieur d'une zone occupée par la première électrode respective ;
10 une seconde électrode sur ou au-dessus des couches luminescentes ; et
un film de protection formé sur ou au-dessus de la seconde électrode.

13. Dispositif organique EL selon la revendication 12, dans lequel le composé organique est un composé organique polymère.

15 14. Dispositif organique EL selon la revendication 13, dans lequel le composé organique polymère est une matière ayant les fonctions d'injection de trous et de transfert de trous.

20 15. Dispositif organique EL selon la revendication 13, dans lequel le composé organique polymère est un vinylène polyparaphénylène ou son dérivé ou un copolymère qui contient au moins l'un quelconque de ces composés.

25 16. Dispositif organique EL selon la revendication 12, dans lequel trois types de couches luminescentes ayant trois couleurs différentes sont formés, et au moins deux types de couches luminescentes parmi les trois types de couches luminescentes sont formés par une formation de motifs au moyen d'un système à jet d'encre.

30 17. Dispositif organique EL selon la revendication 16, dans lequel lesdites trois couleurs comprennent le rouge, le vert et le bleu, et la couche luminescente rouge et la couche luminescente verte sont formées par une formation de motifs au moyen du système à jet d'encre.

35 18. Dispositif organique EL selon la revendication 17, dans lequel la couche luminescente bleue est formée par un procédé de dépôt sous vide.

19. Dispositif organique EL selon la revendication 18, dans lequel la couche luminescente bleue est faite d'une matière ayant les fonctions d'injection d'électrons et de transfert d'électrons.

35 20. Dispositif organique EL selon la revendication 12, dans lequel au moins une couche luminescente est laminée sur une couche de transfert et d'injection d'électrons.

40 21. Dispositif organique EL selon la revendication 12, dans lequel lesdites premières électrodes sont formées en tant que premières électrodes transparentes.

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FIG. 1

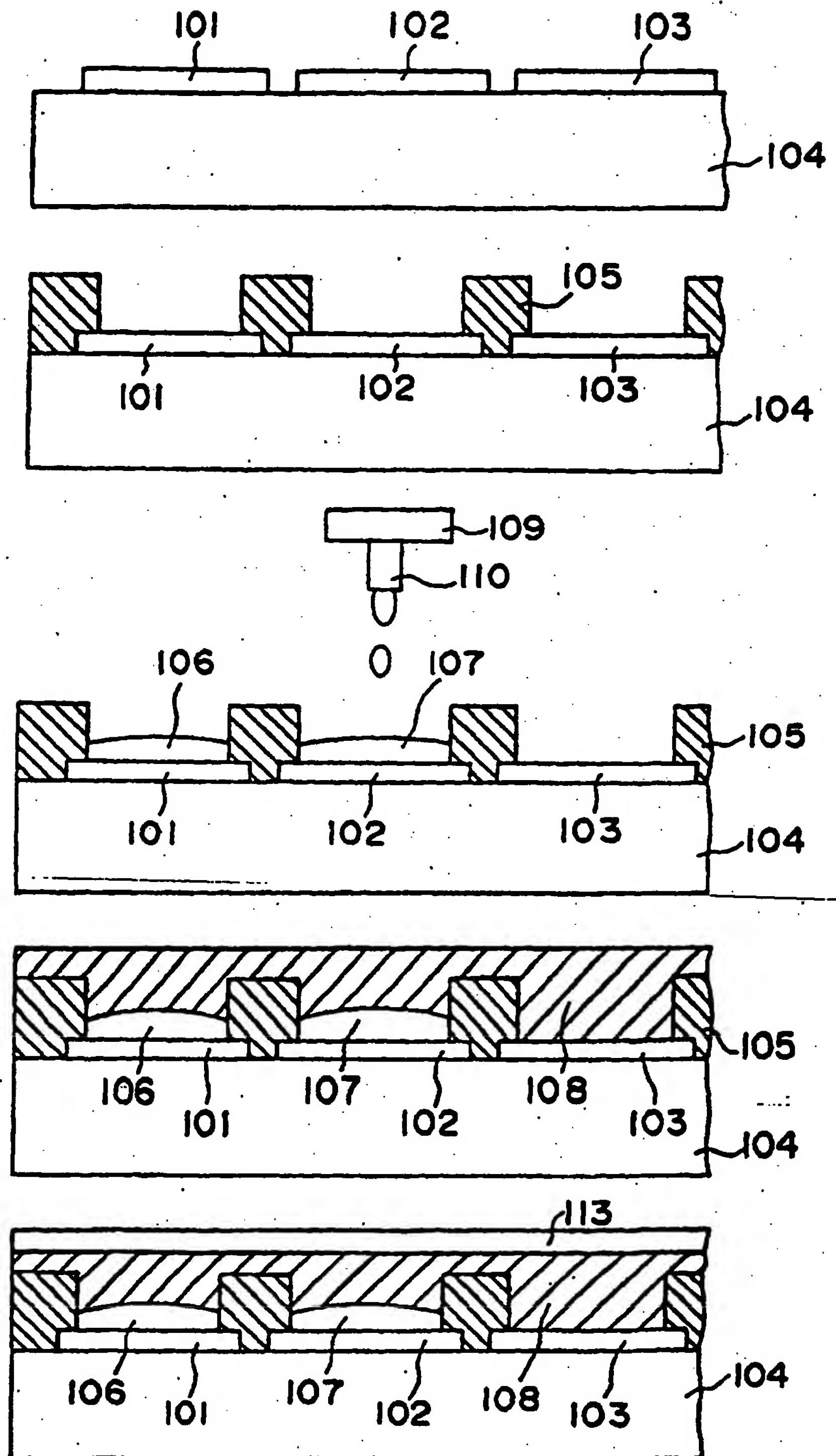


FIG. 2

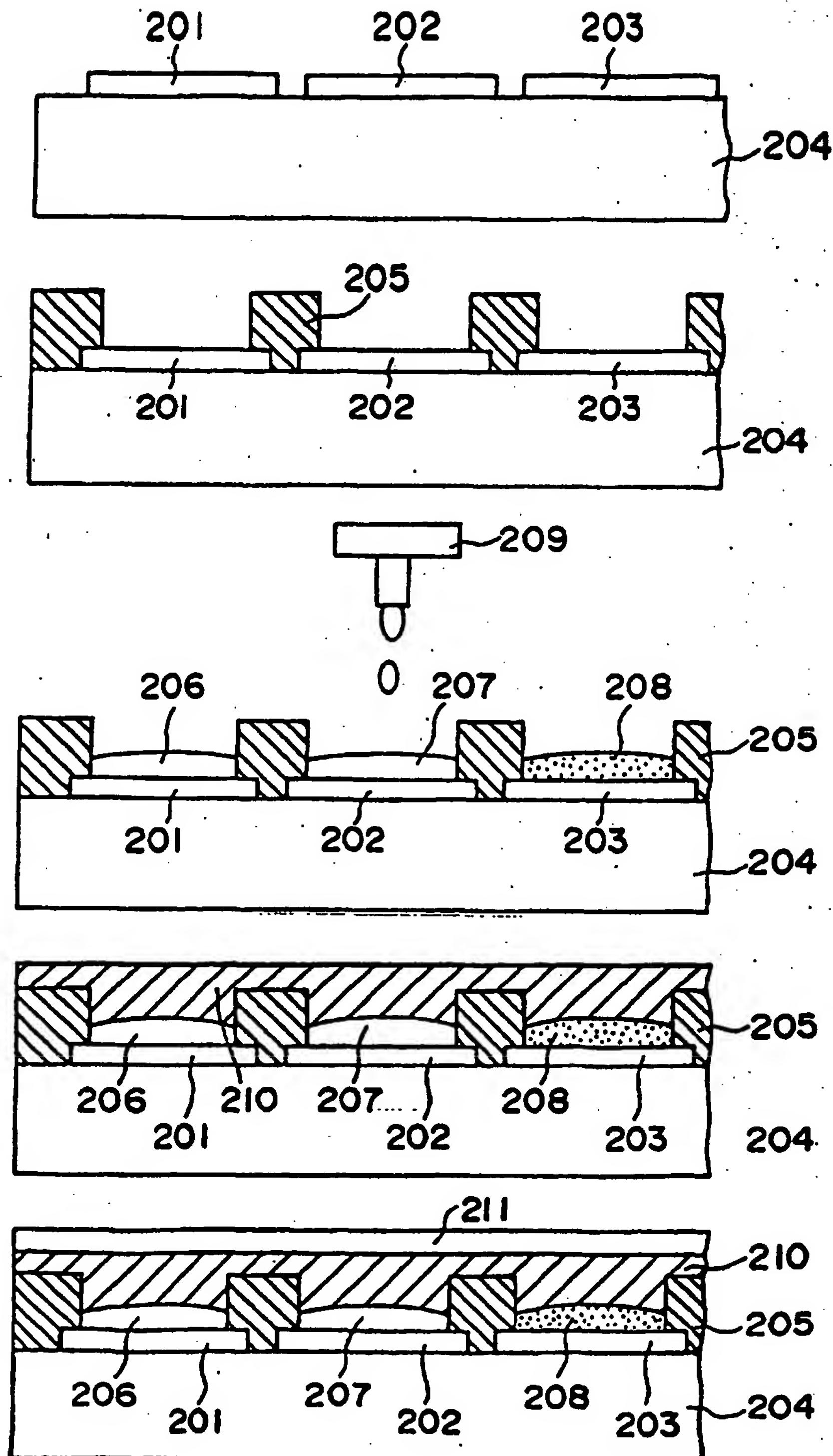


FIG. 3

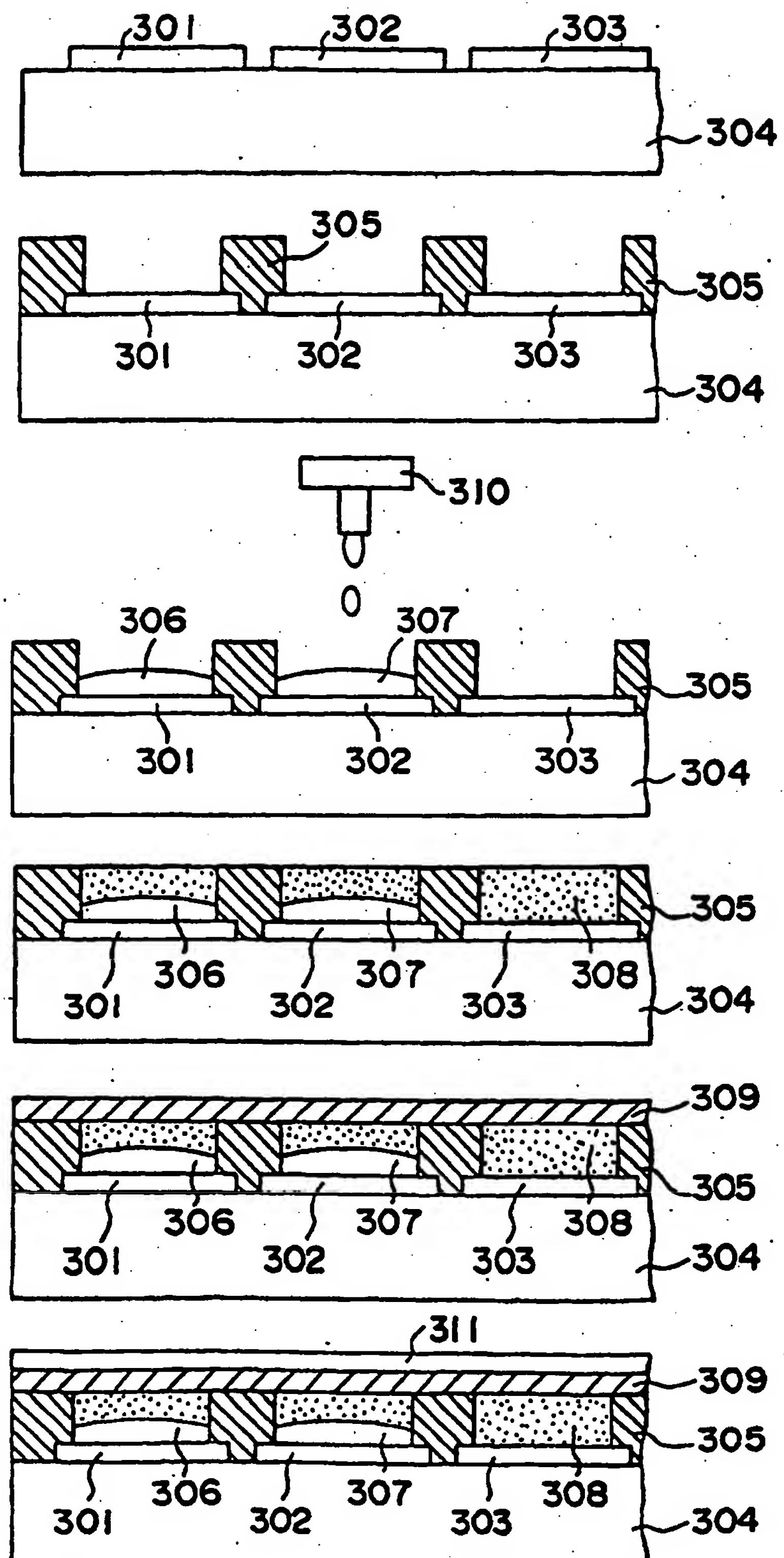


FIG. 4

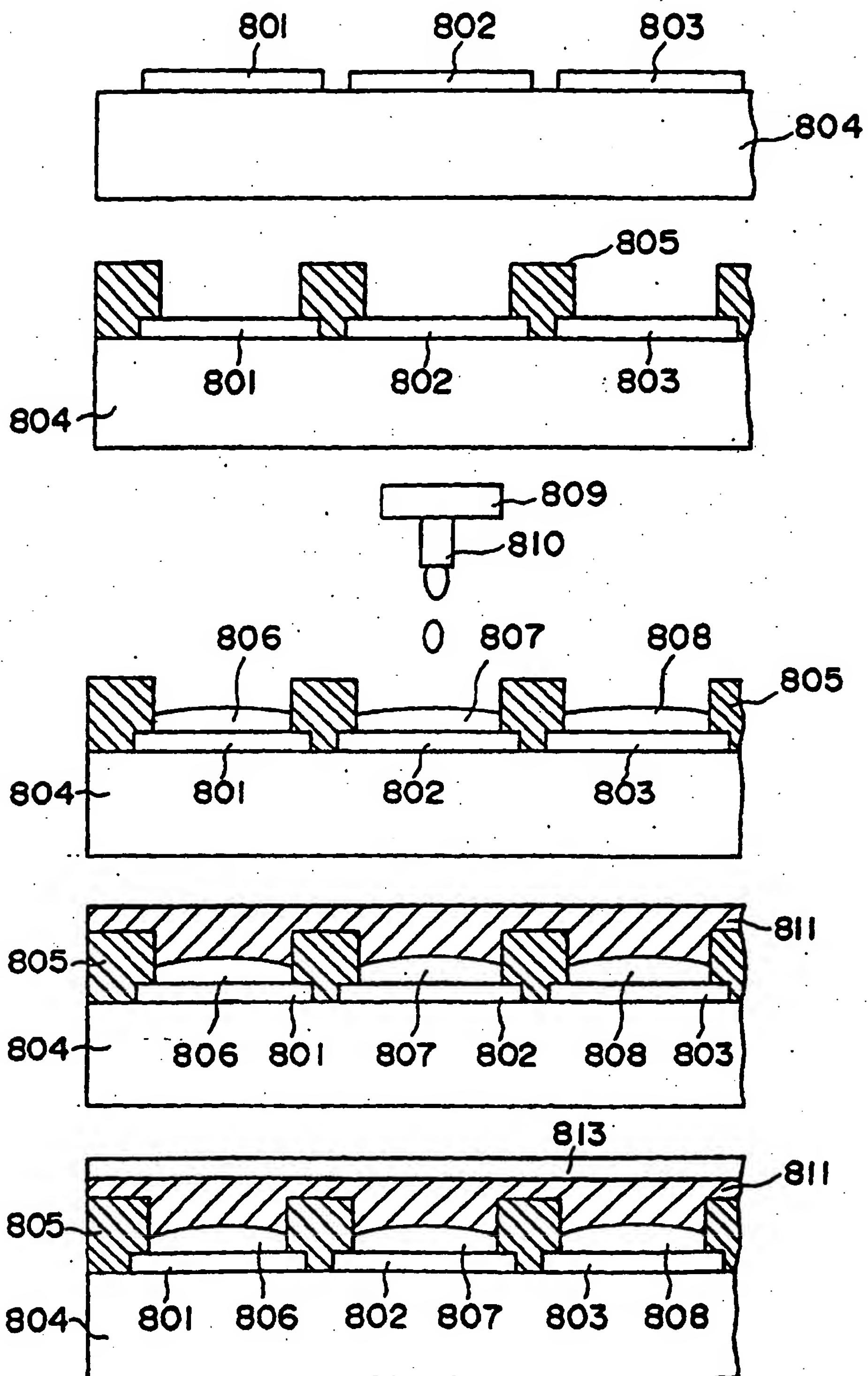


FIG. 5

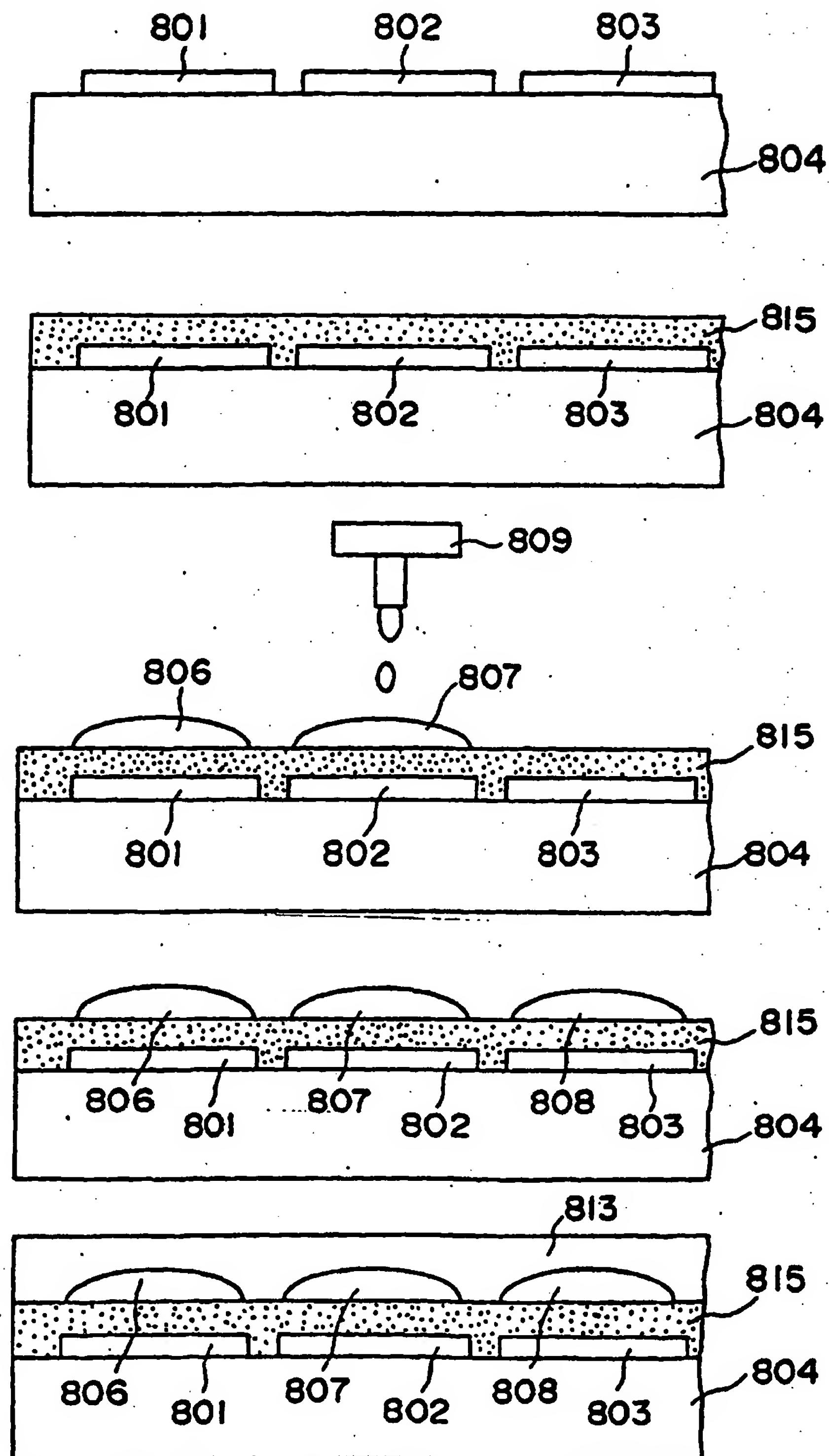


FIG. 6

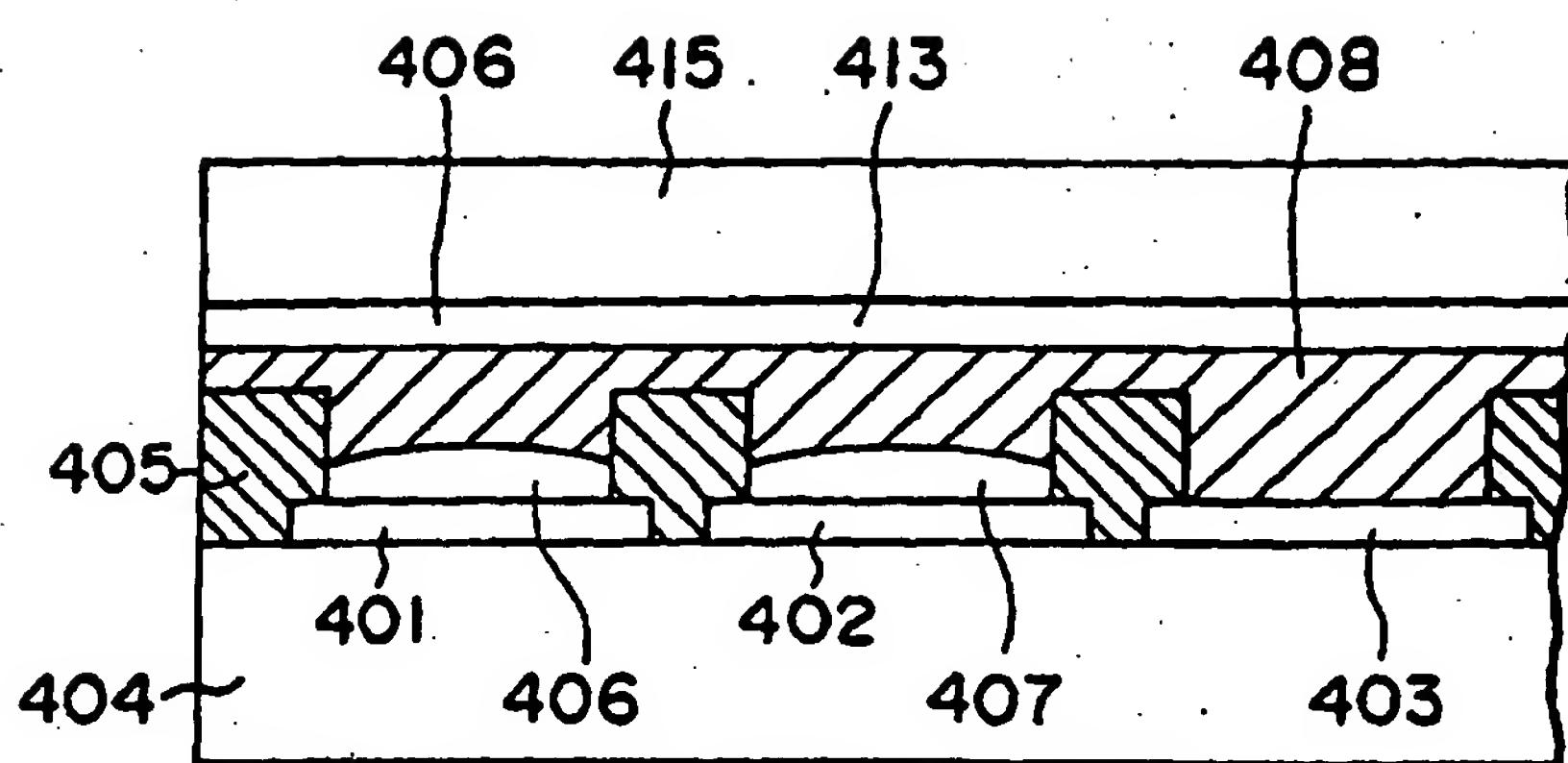


FIG. 7

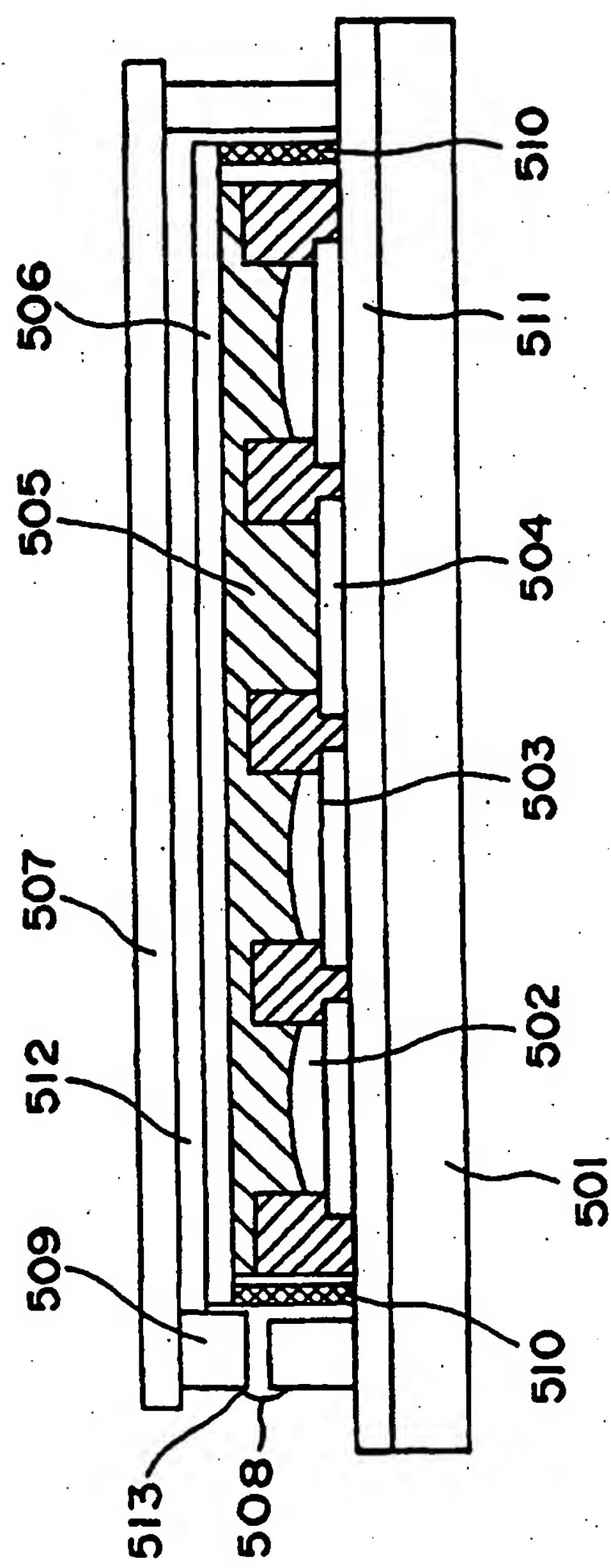


FIG. 8

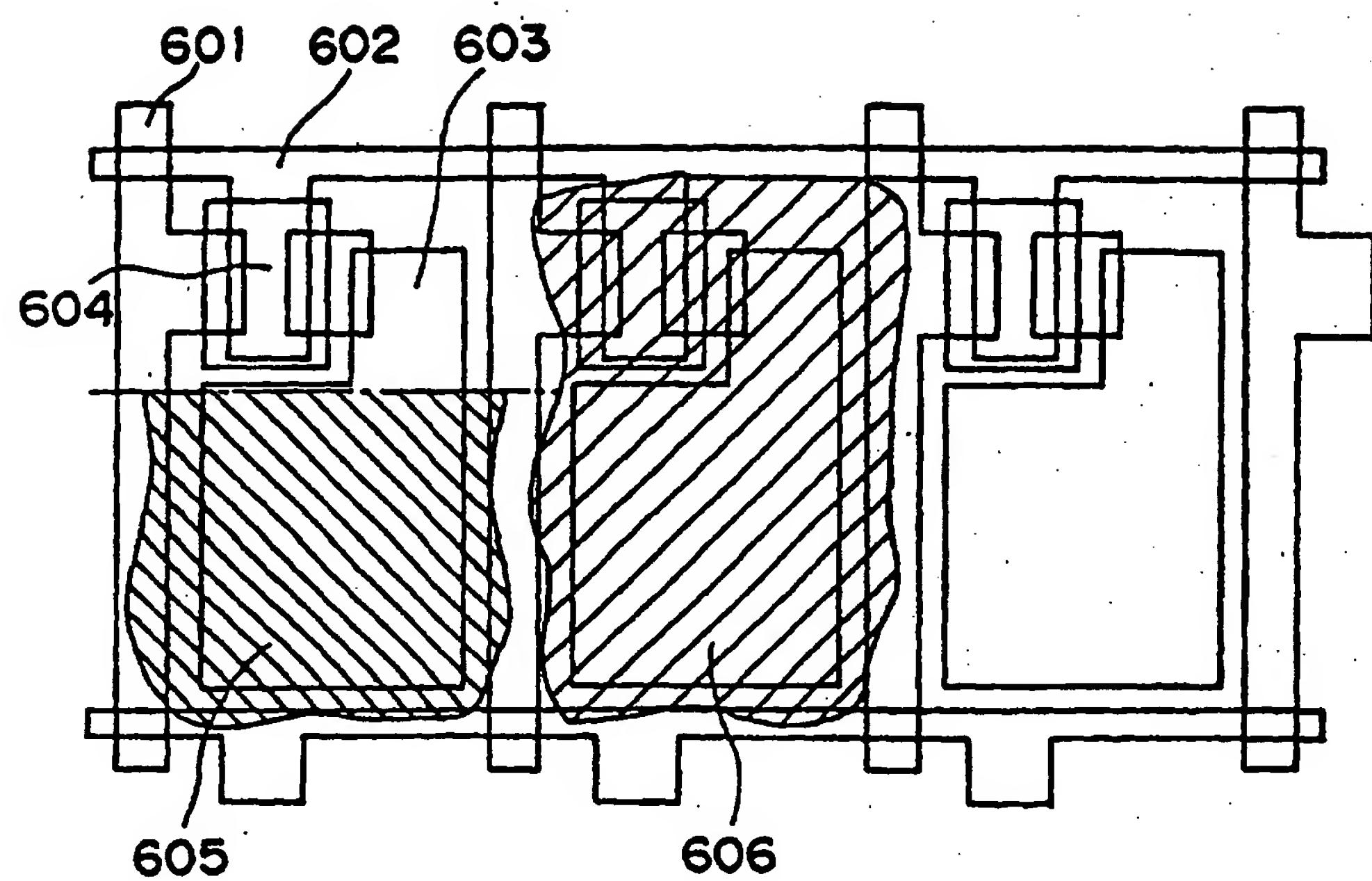


FIG. 9

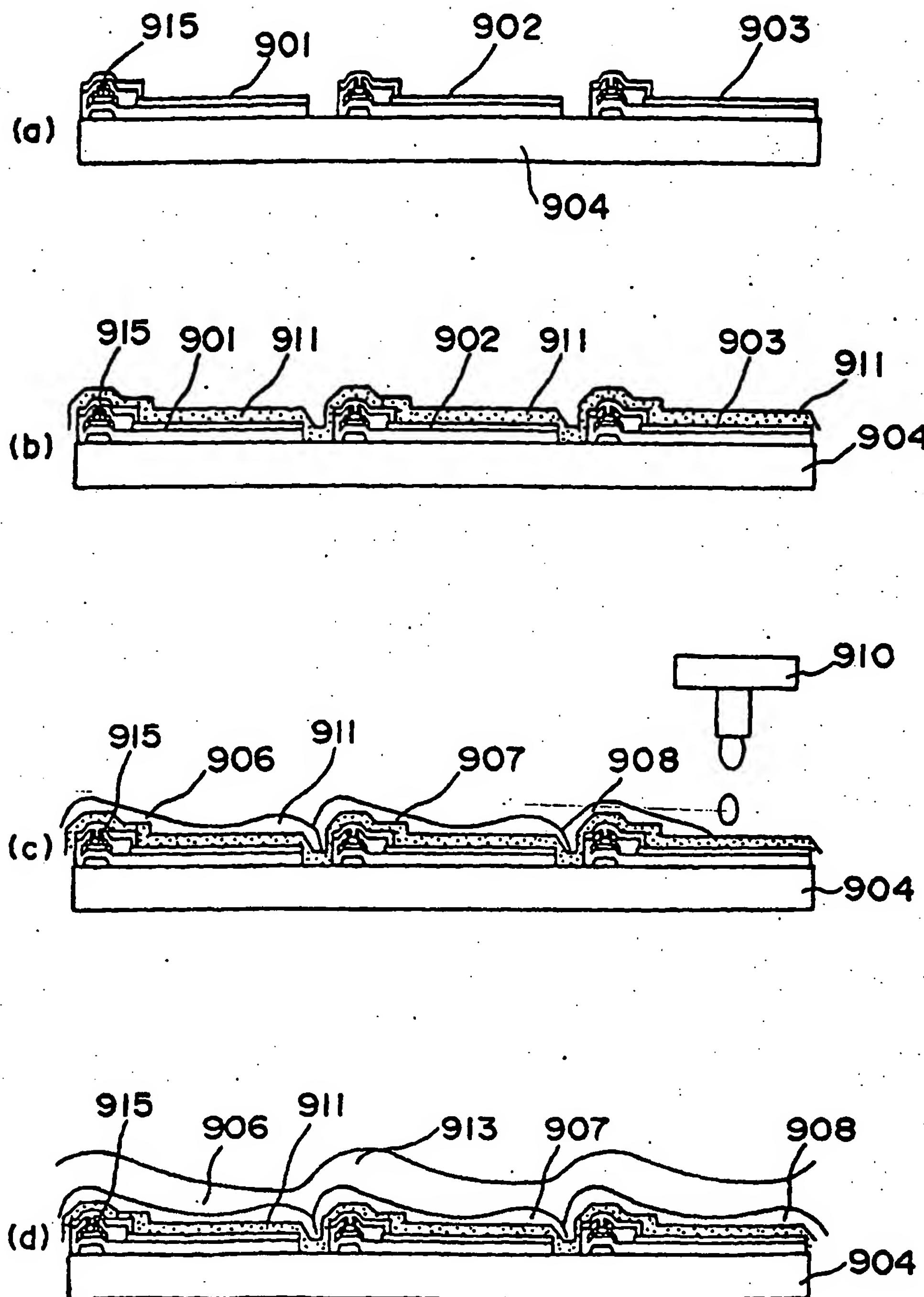


FIG. 10

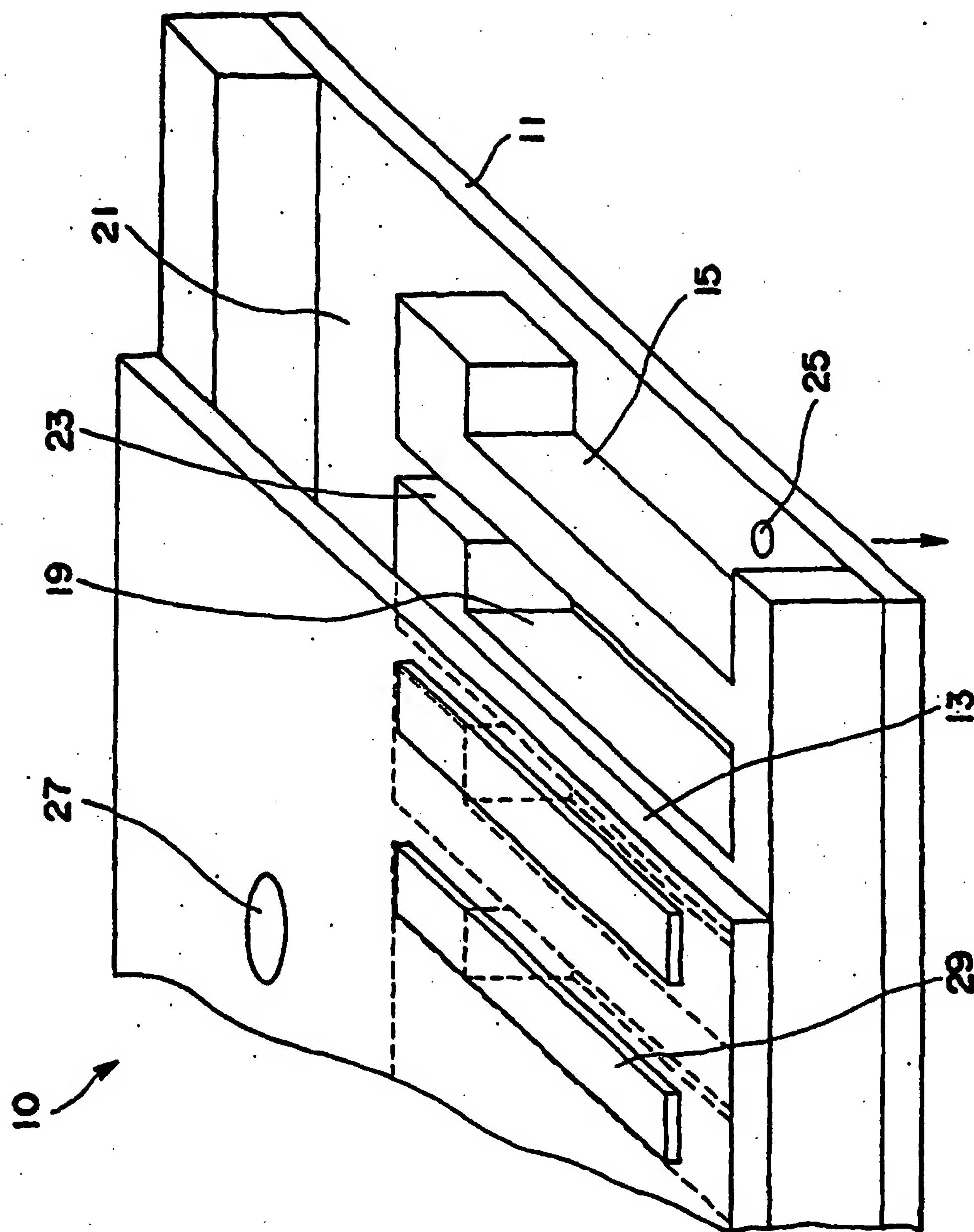


FIG. 11

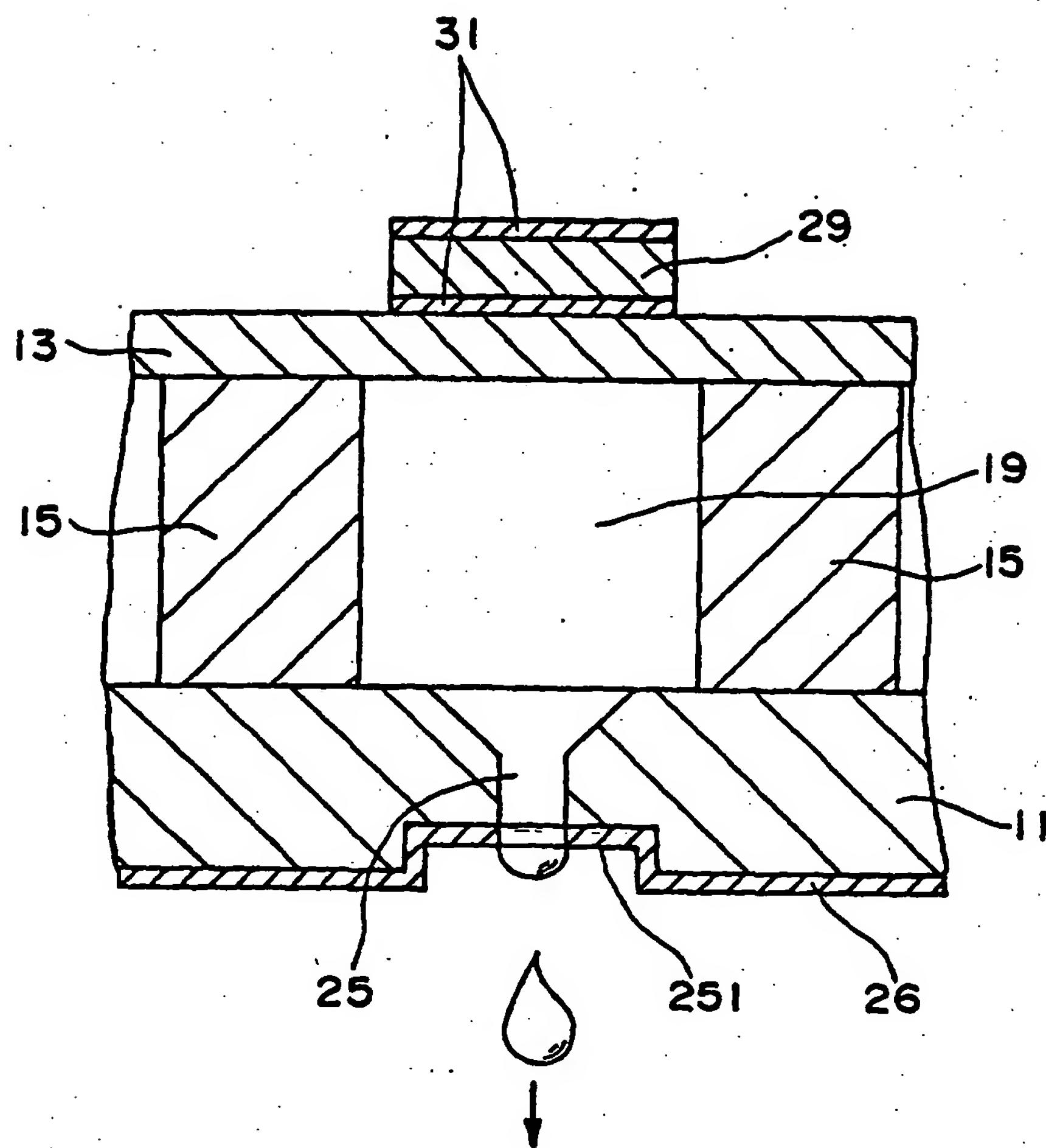


FIG. 12

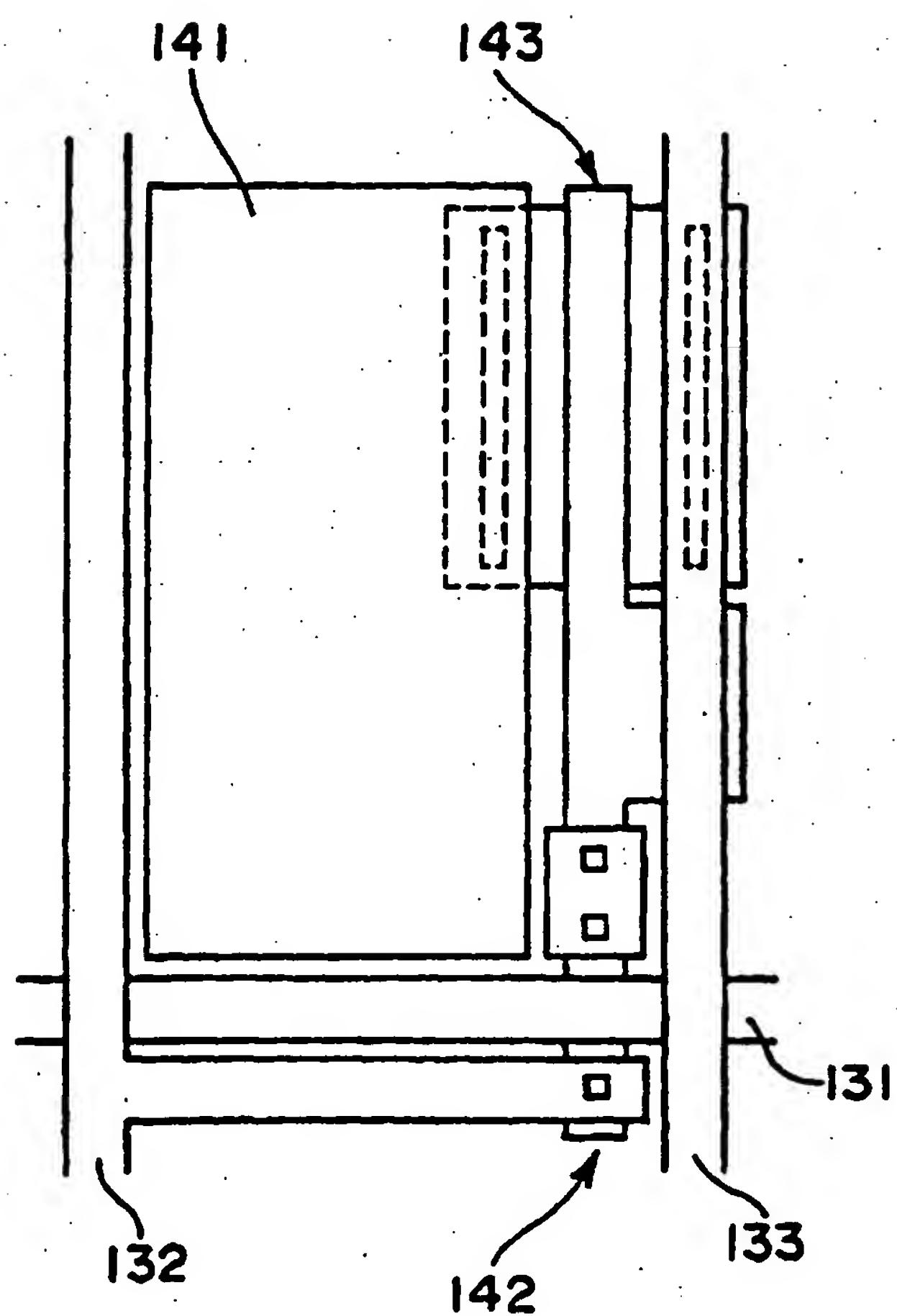


FIG. 13

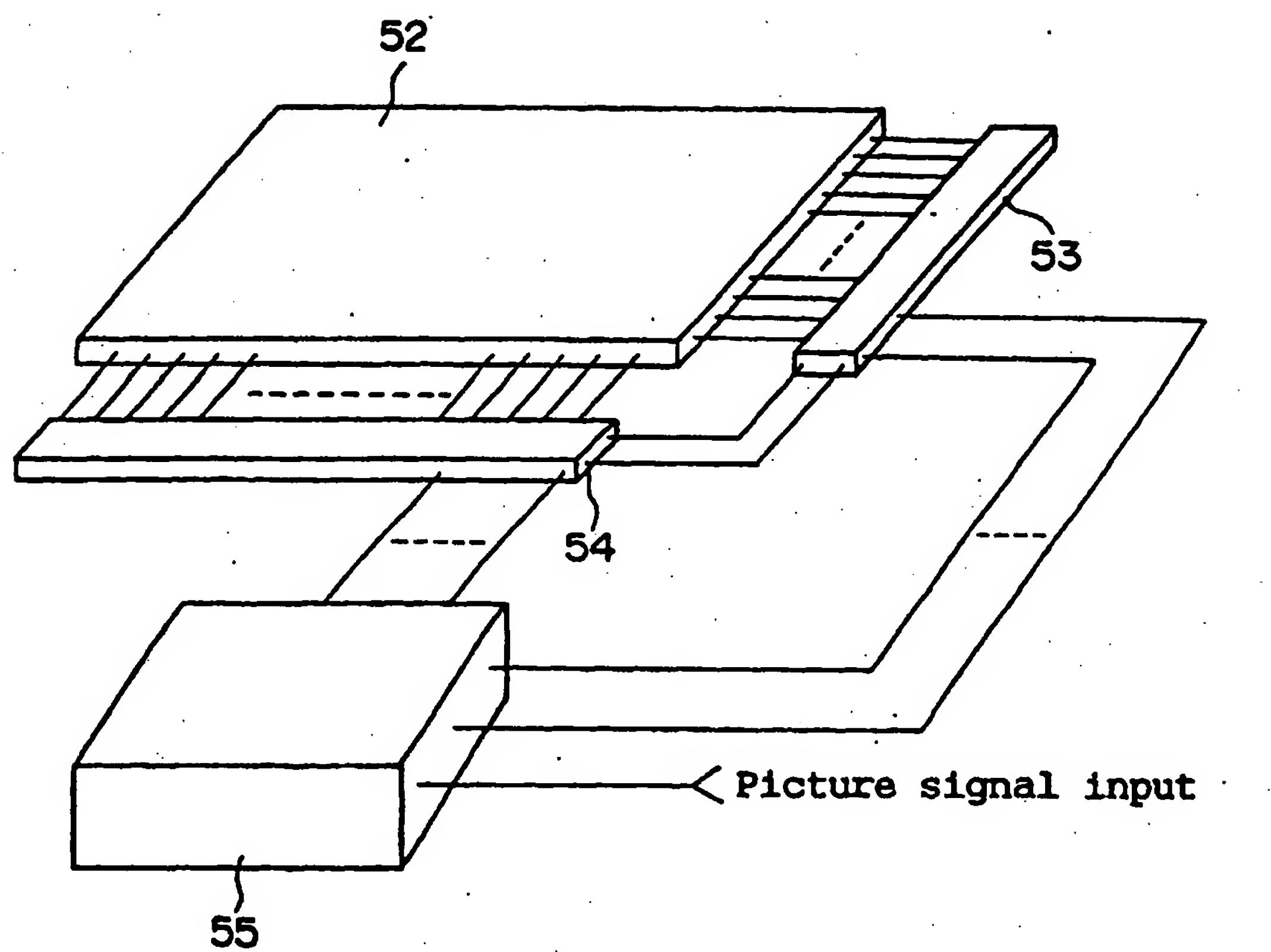


FIG. 14

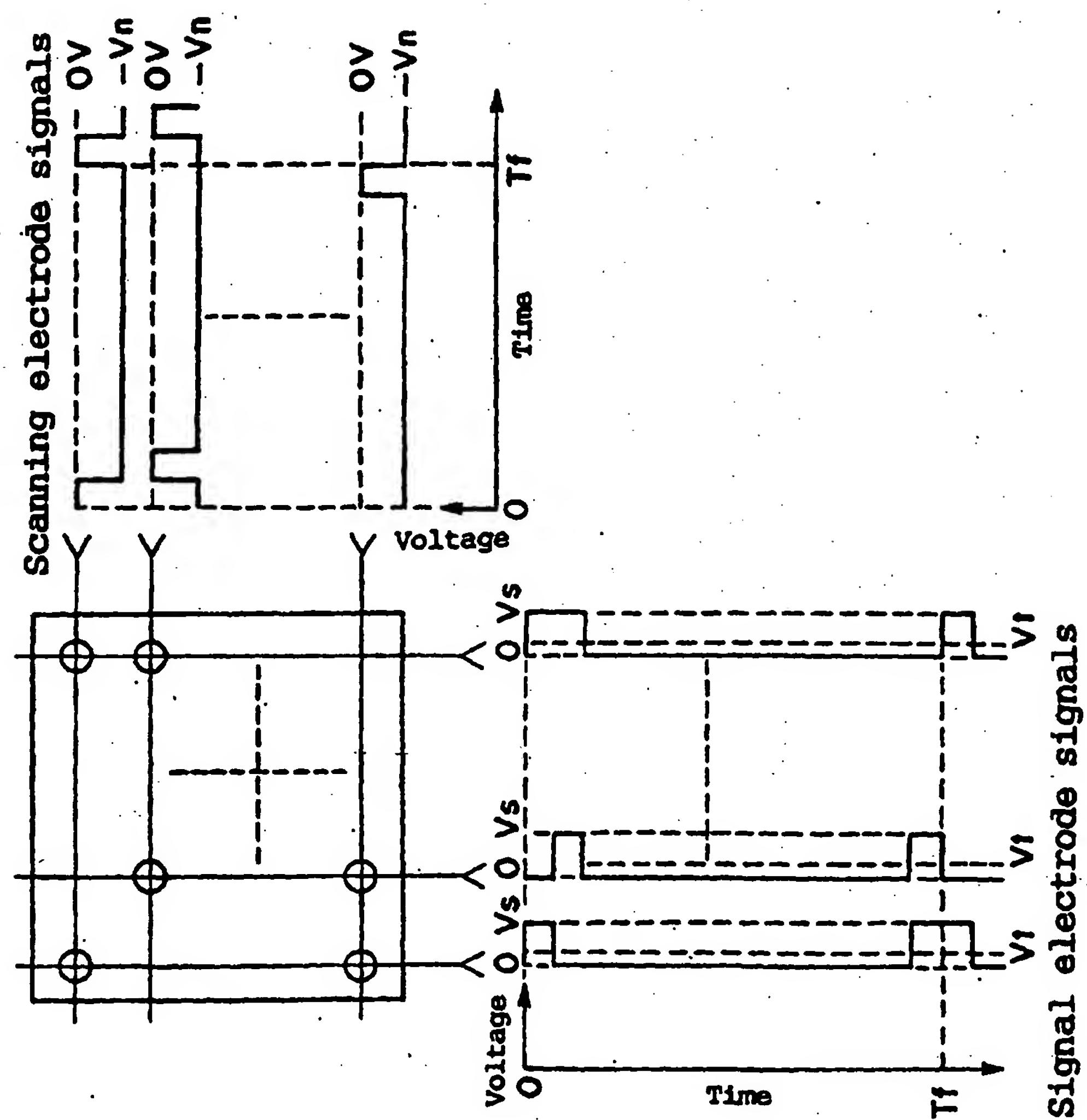
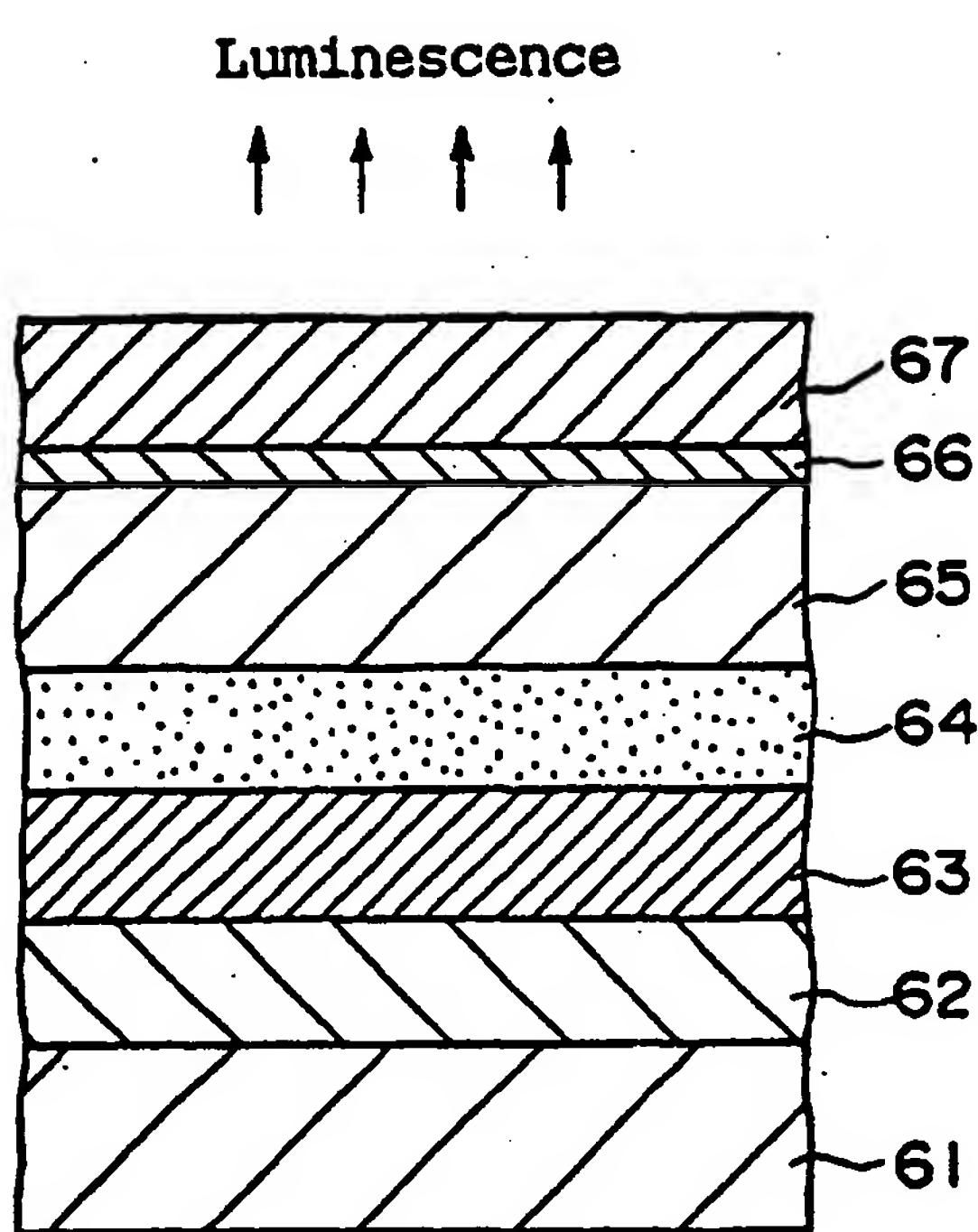


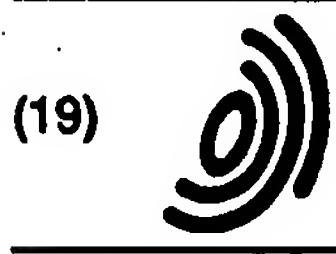
FIG. 15



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(71) Applicant:
Cambridge Display Technology Limited
Cambridge, CB3 0DJ (GB)

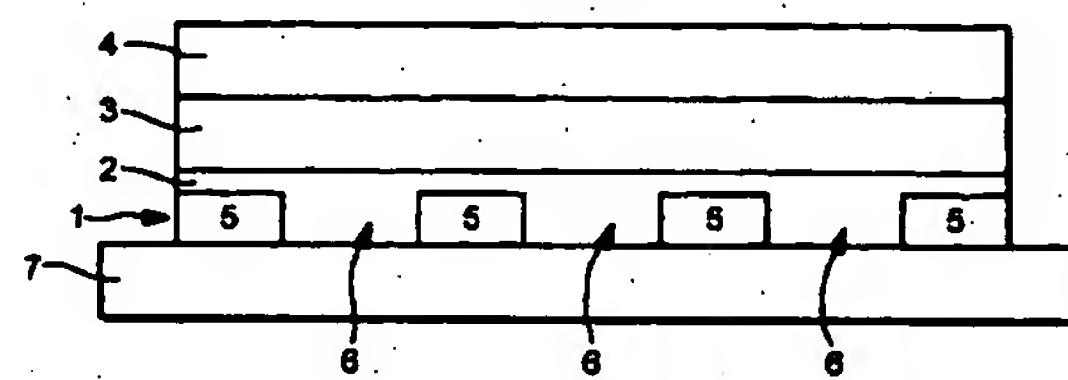
(72) Inventors:
• Towns, Carl Robert
Stanstead, Essex CM24 8HB (GB)
• Heeks, Karl Stephen
Cottenham, Cambridge CB4 4JJ (GB)
• Carter, Julian Charles
Chesterton, Cambridge CB4 1 NZ (GB)

(74) Representative:
Slingsby, Phillip Roy et al
Page White & Farrer
54 Doughty Street
London WC1N 2LS (GB)

(54) Electroluminescent device

(57) An electroluminescent device comprising: a first charge-carrier injecting layer for injecting positive charge carriers and a second charge-carrier injecting layer for injecting negative charge carriers, at least one of the charge-carrier injecting layers being patterned so as to comprise spaced-apart charge-injecting regions; an organic light-emitting layer located between the first and second charge-carrier injecting layers; and an unpatterned conductive polymer layer located between the organic light-emitting layer and the patterned charge-carrier injecting layer, the resistivity of the conductive polymer layer being sufficiently low to allow charge carriers to flow through it from the charge-injecting regions to generate light in the organic light-emitting layer but sufficiently high to resist lateral spreading of charge carriers beyond the charge-injecting regions.

FIG. 1



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Description

[0001] This invention relates to electroluminescent devices, especially ones that have a conjugated polymer as a light-emitting layer.

[0002] One type of electroluminescent device is described in PCT/WO90/13148, the contents of which are incorporated herein by reference. The basic structure of this device is a light-emitting polymer film (for instance a film of a poly(p-phenylenevinylene) - "PPV") sandwiched between two electrodes, one of which injects electrons and the other of which injects holes. It is believed that the electrons and holes excite the polymer film, emitting photons. These devices are useful as flat panel displays, in which case one of the electrodes is transparent - for example being made of indium-tin oxide ("ITO").

[0003] One refinement of the device is that to allow the device to display information one of the electrodes can be patterned so that it only injects charge carriers over part of its area. The electrode can be patterned into discrete areas which can be controlled independently and each inject charge carriers into a respective discrete pixel of the polymer film.

[0004] Another refinement is that it has been found that the turn-on voltage, the brightness of the device at low voltage, the efficiency, the lifetime and the stability of the device can sometimes be improved by adding a layer of conductive polymer between the light-emitting film and one of the electrodes. In order to achieve these benefits these conductive polymer layers typically have a sheet resistance less than 10^6 Ohms/square (i.e. a sheet resistance less than 10^6 Ohms/square), the conductivity being controllable by doping of the polymer layer. One example of a suitable conductive polymer is polystyrene sulphonic acid doped polyethylene dioxythiophene ("PEDT-PSS") - see EP 0,686,662. For reasons which are discussed in more detail below, it is, however, difficult to produce good devices with an intermediate conductive polymer layer.

[0005] There have been some devices which could be regarded as a hybrid of these refinements. For instance, US 5,399,936 discloses a device in which the patterned electrode is covered by a hole-transporting/injecting organic layer of diphenyl-N-N'-bis(3-methylphenyl)-1,1'-biphenyl-4,4'-diamine ("TPD"). However, the TPD is a small molecule, not a polymer, and it is undoped. WO 96/08047 discloses a device in which a conductive polymer layer is patterned to provide insulative regions and conductive regions to pixelate the display.

[0006] According to the present invention there is provided an electroluminescent device comprising: a first charge-carrier injecting layer for injecting positive charge carriers and a second charge-carrier injecting layer for injecting negative charge carriers, at least one of the charge-carrier injecting layers being patterned so as to comprise spaced-apart charge-injecting regions; an organic light-emitting layer located between the first

and second charge-carrier injecting layers; and an unpatterned conductive polymer layer located between the organic light-emitting layer and the patterned charge-carrier injecting layer, the resistivity of the conductive polymer layer being sufficiently low to allow charge carriers to flow through it from the charge-injecting regions to generate light in the organic light-emitting layer but sufficiently high to resist lateral spreading of charge carriers beyond the charge-injecting regions.

[0007] The patterned charge injecting layer could be an anode or a cathode. The other charge injecting layer (of opposite polarity) may be patterned or unpatterned. The width of the charge injecting regions is suitably less than 1mm, 300 μ m or 100 μ m, preferably less than 50 μ m and most preferably less than or around 20 μ m. The spacing between the charge injecting regions is suitably less than 1mm, 300 μ m or 100 μ m, preferably less than 50 μ m and most preferably less than or around 20 μ m.

[0008] The cathode is preferably a sputtered cathode. The cathode is preferably a low work function cathode. The cathode may be patterned by dry etching.

[0009] The light-emitting layer preferably is or comprises a semiconductive conjugated polymer such as PPV. The light-emitting layer suitably is or comprises PPV, poly(2-methoxy-5(2'-ethyl)hexyloxyphenylenevinylene) ("MEH-PPV"), a PPV-derivative (e.g. a di-alkoxy derivative), a polyfluorene and/or a co-polymer incorporating polyfluorene segments, PPVs and/or related co-polymers. It could be deposited by spin-coating, dip-coating, blade-coating, meniscus-coating, self-assembly etc. The constituent of the light-emitting layer and/or its precursor is suitably water-based: examples are precursor-based PPVs. The thickness of the light-emitting layer is preferably in the range from 20 to 200nm and most preferably around 100nm.

[0010] The term "conjugated" indicates a polymer for which the main chain is either fully conjugated, possessing extended pi molecular orbitals along the length of the chain, or is substantially conjugated, but with interruptions to conjugation at various positions, either random or regular, along the main chain. It includes within its scope homopolymers and copolymers.

[0011] The conductive polymer layer preferably is or comprises polyethylene dioxythiophene ("PEDT"), polystyrene sulphonic acid doped polyethylene dioxythiophene ("PEDT-PSS"), doped polyaniline, a doped alkylthiophene and/or a doped polypyrrole. The thickness of the layer is suitably less than 200nm, preferably less than 100nm and most preferably less than or around 50nm. The sheet resistance of the layer is suitably greater than 10^6 or 10^7 Ohms/square, preferably greater than 10^8 Ohms/square and most preferably greater than or around 10^{10} Ohms/square.

[0012] The conductivity of the conductive polymer layer is preferably adjustable (e.g. by means of additive components) over a relatively wide range. The conductive polymer is preferably doped with one or more components that influences its conductivity (e.g. polystyrene

sulphonic acid ("PSS") or epoxy-silane). The conductive polymer is suitable polyaniline, polypyrrole or a poly-thiophene.

[0013] The conductive polymer is preferably adapted to reduce its solubility and/or its interaction with an adjacent layer, especially a polymer layer. This layer is preferably the subsequent layer and most preferably the light emitting layer. To achieve this the conductive polymer preferably contains an additional component. This component is suitably a cross-linking agent (e.g. epoxy-silane). This component preferably does not significantly impair the performance of the device, especially by increasing the drive voltage significantly, reducing the emission uniformity significantly or reducing the efficiency significantly. This component is especially advantageous in a device in which the conductive polymer and the light-emitting layer have the same or similar solvents. The amount of this component in the conductive polymer layer is suitably greater than 50wt%, preferably between 50wt% and 200wt% and most preferably around 100wt%.

[0014] Where the conductive polymer is PEDT-PSS the dilution of the PEDT-PSS with the PSS is preferably greater than 20% and most preferably greater than 50%. Any of these proportions may be used together with any of the proportions of epoxy-silane disclosed above.

[0015] The resistance of the conductive polymer layer is suitably such as to require an increase in the drive voltage of the device (compared to when the layer is absent) of 0.5V or less (preferably 0.2V or less) for equivalent device performance.

[0016] The present invention will now be described by way of example with reference to the accompanying drawings, in which:

figure 1 shows a cross-section of an electroluminescent device; and

figure 2 shows the chemical formula of PEDT-PSS.

[0017] Figure 1 shows an electroluminescent device having an anode layer 1 for injecting positive charge carriers, a conductive polymer layer 2, an organic light-emitting layer 3 and a cathode layer 4 for injecting negative charge carriers. The anode is patterned so as to comprise charge-injecting regions 5 (defining pixels) which are spaced from each other by gaps 6. The conductivity of the conductive polymer layer is selected so as to be low enough to allow for normal operation of the device (for instance, not so high that the drive voltage is increased significantly or that the efficiency or uniformity drops significantly) but high enough to resist cross-talk and lateral current-spreading between the charge-injecting regions and to resist off-pixel emission (so that the pixel edges are sharp and well-defined and there is no fuzzy emission edge to the pixels).

[0018] In more detail, the anode 1 is a layer of indium-tin oxide ("ITO") having a thickness of approximately

150nm. The widths of the pixel regions 5 and the gaps 6 are around 50μm.

[0019] The conductive polymer layer is a layer of PEDT-PSS with a thickness of around 50nm and a conductivity of around 10⁸ Ohms/square. The layer also contains around 100wt% epoxy-silane to produce cross-linking.

[0020] The light-emitting layer 3 is a layer of PPV having a thickness of 100nm.

[0021] The cathode 4 is a layer of aluminium, having a thickness of 150nm.

[0022] The relatively high resistance of the conductive polymer layer resists cross-talk between the charge-injecting regions 5, with lateral off-pixel emission being restricted to within 10 or 5% of the pixel dimension and/or leakage of current outside the pixel boundary being restricted to 5 or 10% of the total current through the addressed pixel. And surprisingly, it has been found that even at conductivities of the conductive polymer layer as low as 10¹⁰ Ohms/square the performance of the device is not necessarily impaired, the increase in drive voltage required being minimal.

[0023] A rough guide to the conductivity of the polymer layer that is required can be estimated with the aid of the following relationships:

for isotropic homogeneous conductivity media, the voltage drop across a device is given by:

$$V_d = j \perp R_{\square} t^2$$

j = current/area

t = thickness in units of area⁻¹

R_{\square} = sheet resistivity in Ω/□

whereas the current between the ITO lines is:

$$j_{\parallel} = (V A) / R_{\square}$$

A = aspect ratio of space between ITO lines

[0024] Clearly, the minimum advisable thickness of the polymer layer is dependant on the reliability of the process used to deposit the layer - if the layer is uneven and too thin in places then the anode and the light-emitting layer could make contact.

[0025] To produce the device, first the anode is deposited (on a glass substrate 7 for example) and patterned, e.g. by laser scribing, to define the charge-injecting and non-charge injecting regions. The charge injecting regions are connected individually to a control circuit so that they can be controlled independently and can thereby define pixel regions of the display, with each pixel region forming a column extending up from the corresponding charge injecting region.

[0026] A PEDT-PSS solution having a ratio of PEDT to PSS of 1:1.6 and a solid content of 1.2 to 1.3% is diluted further with extra PSS to achieve a PEDT to PSS ratio of 1:55 and a solid content of about 1%. Around 100wt%

epoxysilane (specifically 3-glycidyl oxypropyltrimethoxysilane) is then added to the solution and the mixture is deposited on to the anode by spin coating. It is believed that both the PSS and the epoxy-silane act to reduce the conductivity of the resulting layer. The combination of PSS and epoxy-silane also helps to avoid problems with leakage currents in the pixels which have been experienced when epoxy-silane is used with lower concentrations of PSS. (Further information on this polymer system, which is available from Bayer AG, is given in Bayer's Provisional Product Information Sheet for Trial Product AI 4071).

[0027] After the PEDT-PSS layer has dried the layer of PPV is deposited on to the layer of PEDT-PSS by spin-coating from an aqueous solvent. This process is of itself well-known. It has been experienced that depositing a PPV precursor in this way on top of a layer of PEDT-PSS can dissolve the underlying PEDT-PSS layer, causing non-uniformities in, for instance, the thickness of the layer structure. This can result in non-uniform emission. It has been found that this problem is increased for higher concentrations of PSS in the PEDT-PSS layer, although higher concentrations of PSS can provide advantages in the device's current-voltage characteristics (e.g. less current leakage below the turn-on voltage and in reverse bias) and lifetime. Depositing PPV over a PEDT-PSS layer has also been found to reduce the resistance of the PEDT-PSS layer. However, with epoxy-silane added to the PEDT-PSS layer the layer has been found to be structurally more stable, even at relatively high concentrations of PSS, avoiding the problems of intermixing with a PPV precursor and reduced resistance.

[0028] The cathode is then deposited by sputtering over the PPV layer, for instance by DC magnetron sputtering according to the following procedure. A target of Al95%/Li2.5%/Cu1.5%/Mg1% is used with sputtering in constant power mode at around 3.2Wcm^{-2} (100mm diameter target and 250W), pressure around 5×10^{-3} mbar at 25sccm argon flow (base pressure around 1×10^{-6} mbar), target voltage 400-410V, target-substrate distance 75mm and a deposition rate of around 1nm/s. This tends to produce a metallic cathode of compact morphology with low average grain size and good adhesion to the adjacent organic layer.

[0029] When the device is in operation a voltage is applied across the electrodes and electrons and holes combine in the light emitting region to generate (via, it is believed, excitons) photons which are emitted through the ITO electrode and the glass layer. The recombination process is independent of the physical layering of the device.

[0030] Some alternative embodiments will now be described.

[0031] The light-emitting layer could be PPV (yellow/green) via the precursor route - as described above - or MEH-PPV (orange/red) which could be deposited from an organic solvent.

[0032] Other suitable polymers for the conductive polymer layer include polyaniline, polypyrrole and other poly-thiophenes than PEDT-PSS. In each case, suitable dopants and/or cross linking agents could be added to influence the polymer's properties.

[0033] The layer of conductive polymer could be deposited by a number of methods, including dip-coating, meniscus-coating, self-assembly or doctor-blade-coating.

[0034] Instead of the entire conductive polymer region being unpatterned, some parts of it could be unpatterned and some patterned.

[0035] The cathode could be a calcium cathode, deposited for instance by evaporation.

[0036] Some potential applications for the device are dot-matrix displays including passive matrix displays and active matrix addressed displays. In these devices, each charge-injecting region of the anode typically can selectively provide charge carriers to more than one pixel.

[0037] The present invention may include any feature or combination of features disclosed herein either implicitly or explicitly or any generalisation thereof irrespective of whether it relates to the presently claimed invention. In view of the foregoing description it will be evident to a person skilled in the art that various modifications may be made within the scope of the invention.

Claims

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1. An electroluminescent device comprising:

35 a first charge-carrier injecting layer for injecting positive charge carriers and a second charge-carrier injecting layer for injecting negative charge carriers, at least one of the charge-carrier injecting layers being patterned so as to comprise spaced-apart charge-injecting regions;

40 an organic light-emitting layer located between the first and second charge-carrier injecting layers; and

45 an unpatterned conductive polymer layer located between the organic light-emitting layer and the patterned charge-carrier injecting layer, the resistivity of the conductive polymer layer being sufficiently low to allow charge carriers to flow through it from the charge-injecting regions to generate light in the organic light-emitting layer but sufficiently high to resist lateral spreading of charge carriers beyond the charge-injecting regions.

50 55 2. An electroluminescent device as claimed in claim 1, wherein the light-emitting layer comprises a light-emitting conductive polymer.

3. An electroluminescent device as claimed in claim 1,

wherein the light-emitting layer comprises a semi-conductive conjugated polymer.

4. An electroluminescent device as claimed in any preceding claim, wherein the conductive polymer layer comprises polyaniline, polypyrrole or a polythiophene. 5

5. An electroluminescent device as claimed in any preceding claim, wherein the conductive polymer layer comprises polyethylene dioxythiophene. 10

6. An electroluminescent device as claimed in any preceding claim, wherein the conductive polymer layer comprises a dopant, the presence of which affects the resistivity of the conductive polymer layer. 15

7. An electroluminescent device as claimed in claim 6, wherein the dopant is polystyrene sulphonic acid. 20

8. An electroluminescent device as claimed in claim 6 or 7, wherein the conductive polymer layer contains greater than 50% dopant. 25

9. An electroluminescent device as claimed in any preceding claim, wherein the conductive polymer layer comprises a component which reduces the solubility of the layer. 30

10. An electroluminescent device as claimed in claim 8, wherein the component is epoxy-silane. 35

11. An electroluminescent device as claimed in claim 9 or 10, wherein the conductive polymer layer contains greater than 50wt% of the component. 40

12. An electroluminescent device as claimed in any preceding claim, wherein the sheet resistance of the conductive polymer layer is greater than 10^6 Ohms/square. 45

13. An electroluminescent device as claimed in any preceding claim, wherein the regions of the light emitting layer capable of emitting light in use do not extend laterally beyond the charge injecting regions by more than 10% of the width of the charge injecting regions. 50

14. An electroluminescent device as claimed in any preceding claim, wherein each charge-injecting region defines one or more pixel regions of the device. 55

15. An electroluminescent device as claimed in any preceding claim, wherein each charge-injecting region is independent of the or each other charge-injecting region.

FIG. 1

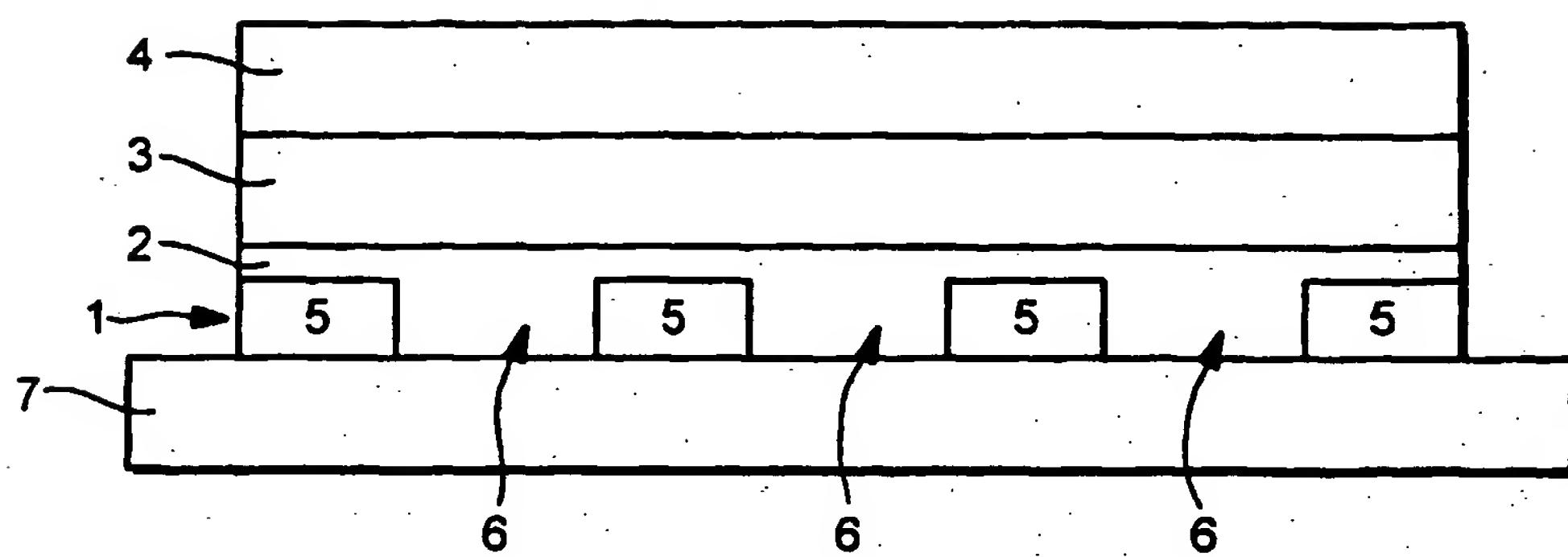
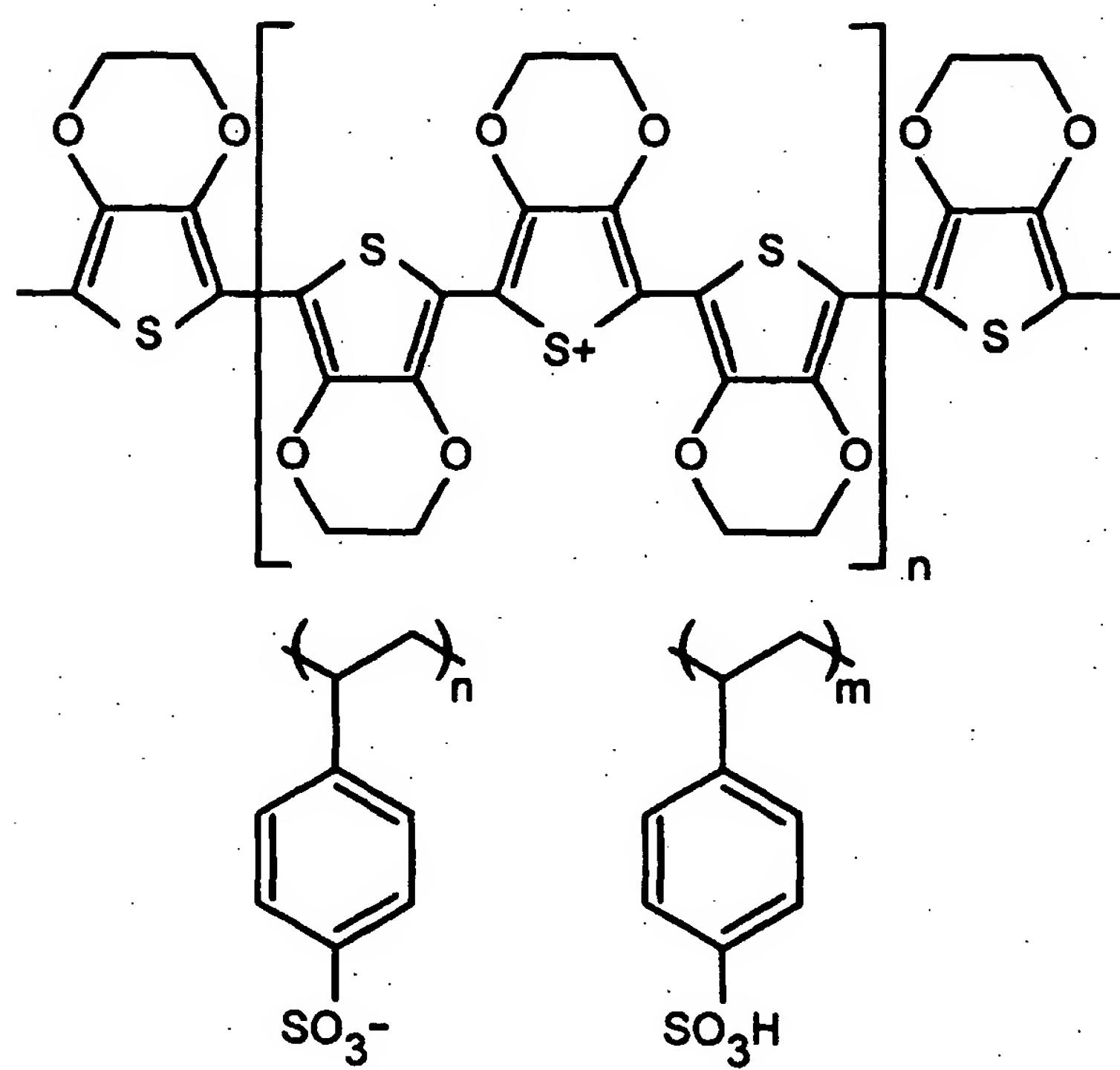


FIG. 2



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(71) Applicant: Cambridge Display Technology
Limited
Cambridge, CB3 0DJ (GB)

(72) Inventors:

- Towns, Carl Robert
Stanstead, Essex CM24 8HB (GB)
- Heeks, Karl Stephen
Cottenham, Cambridge CB4 4JJ (GB)
- Carter, Julian Charles
Chesterston, Cambridge CB4 1 NZ (GB)

(74) Representative: Slingsby, Philip Roy et al
Page White & Farrer

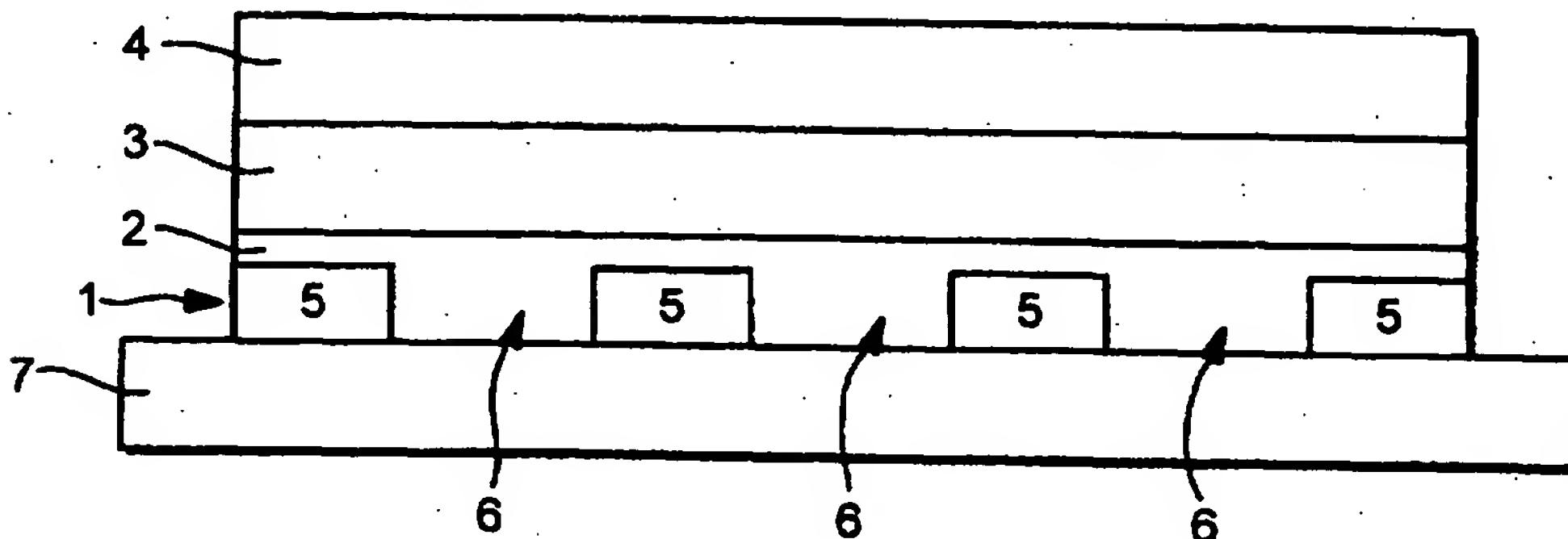
54 Doughty Street
London WC1N 2LS (GB)

(54) Electroluminescent device

(57) An electroluminescent device comprising: a first charge-carrier injecting layer for injecting positive charge carriers and a second charge-carrier injecting layer for injecting negative charge carriers, at least one of the charge-carrier injecting layers being patterned so as to comprise spaced-apart charge-injecting regions; an organic light-emitting layer located between the first and second charge-carrier injecting layers; and an un-

patterned conductive polymer layer located between the organic light-emitting layer and the patterned charge-carrier injecting layer, the resistivity of the conductive polymer layer being sufficiently low to allow charge carriers to flow through it from the charge-injecting regions to generate light in the organic light-emitting layer but sufficiently high to resist lateral spreading of charge carriers beyond the charge-injecting regions.

FIG. 1



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European Patent
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Category	Citation of document with indication, where appropriate, of relevant passages	Relevant to claim							
X	WO 96 31909 A (UNIAX CORP) 10 October 1996 (1996-10-10) * page 24, line 15 - page 27, line 36 *	1-4, 9, 14-16 6, 12, 13	HO1L51/20 HO1L27/00						
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			HO1L						
<p>The present search report has been drawn up for all claims</p> <table border="1" style="width: 100%; border-collapse: collapse;"> <tr> <td style="width: 33%;">Place of search</td> <td style="width: 33%;">Date of completion of the search</td> <td style="width: 34%;">Examiner</td> </tr> <tr> <td>THE HAGUE</td> <td>23 August 2001</td> <td>van der Linden, J.E.</td> </tr> </table> <p>CATEGORY OF CITED DOCUMENTS</p> <p>X : particularly relevant if taken alone Y : particularly relevant if combined with another document of the same category A : technological background O : non-written disclosure P : intermediate document</p> <p>T : theory or principle underlying the invention E : earlier patent document, but published on, or after the filing date D : document cited in the application L : document cited for other reasons & : member of the same patent family, corresponding document</p>				Place of search	Date of completion of the search	Examiner	THE HAGUE	23 August 2001	van der Linden, J.E.
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